

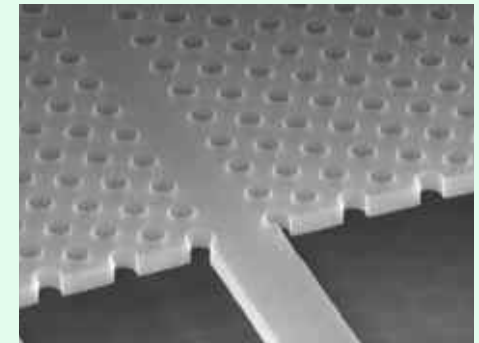
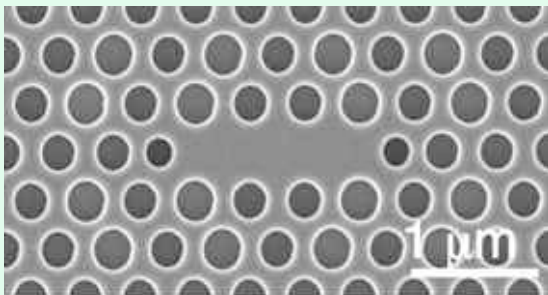


Integrated Nanophotonics: Issues and opportunities

Thomas F Krauss

University of St. Andrews, SUPA, School of Physics and Astronomy,
St Andrews, UK

Key collaborators: Pavia & Catania, Italy





University of St Andrews

St Andrews

Scotland's First University

Thomas F Krauss



universally acknowledged

Scotland's First University



University of St Andrews

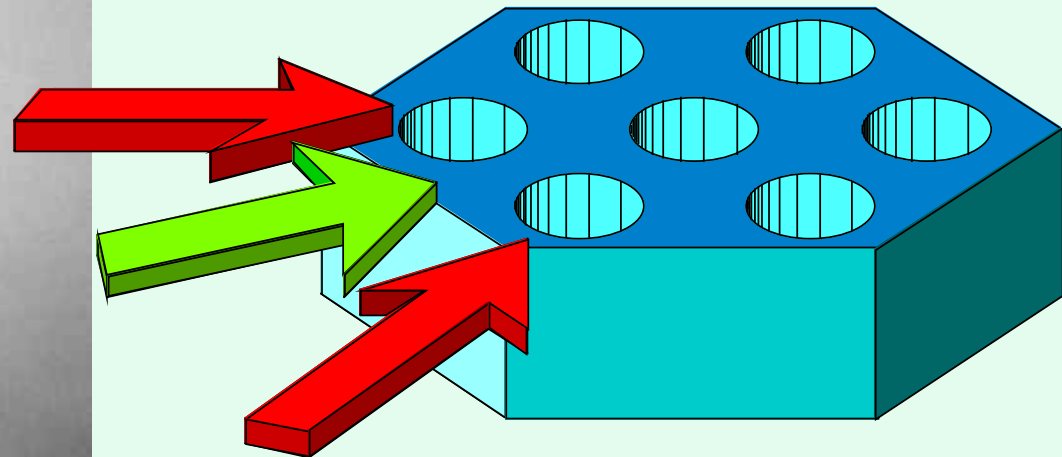


- Scotland, UK
- 18,000 people (1/3 students)
- 80km from Edinburgh
- 600 km from London



universally acknowledged

Scotland's First University

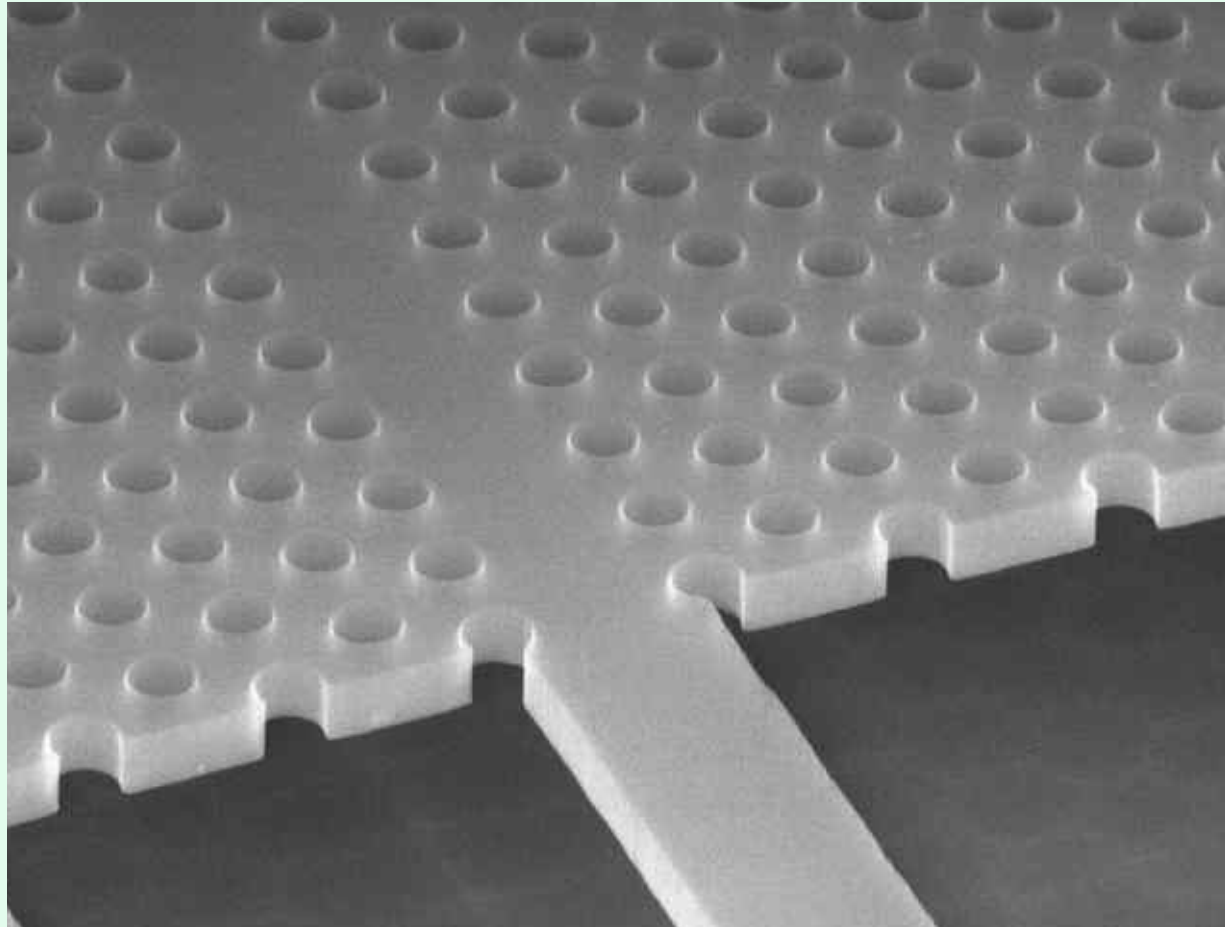




CAIBE machine

TF Krauss, Pavia March 2012 No.6/60

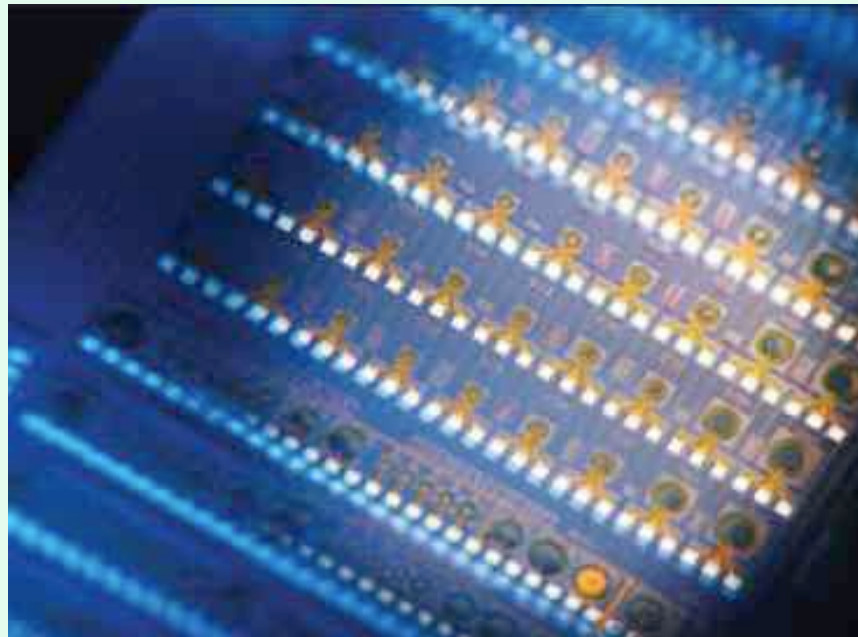





220 nm Si waveguide, airbridge or oxide clad
epixnet nanostructuring platform: www.nanophotonics.eu



Silicon Photonics



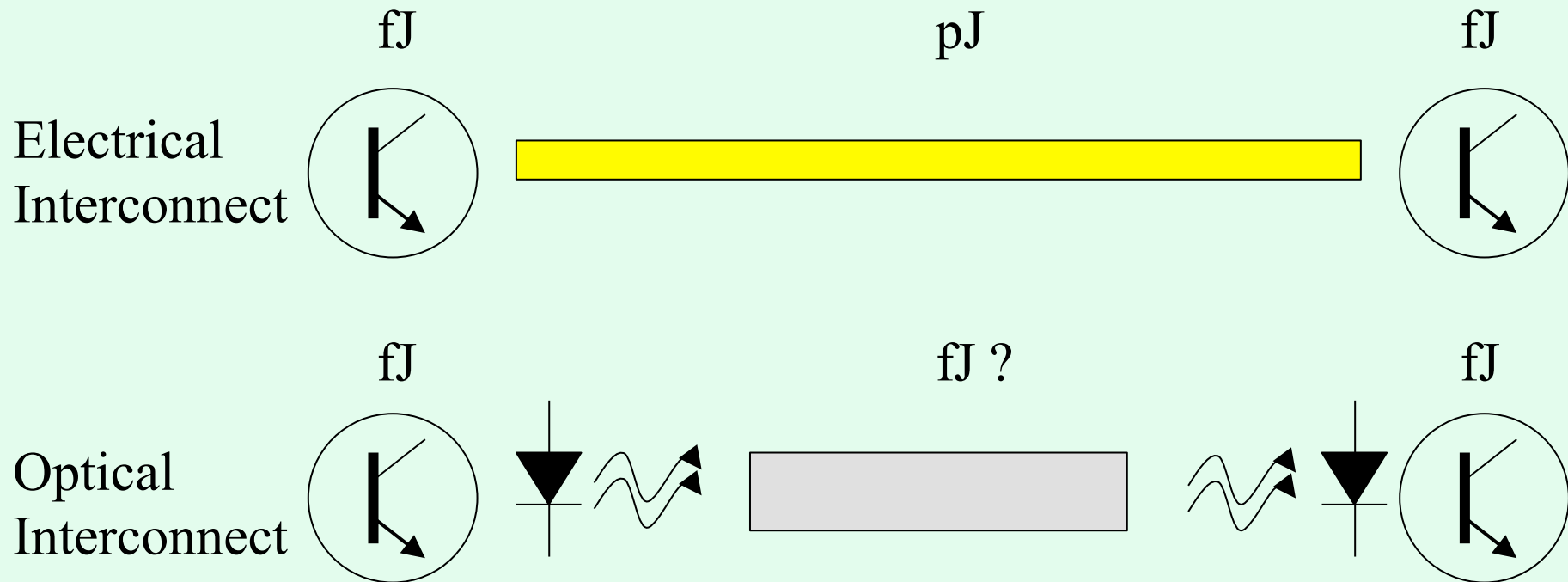
What's the problem silicon photonics is trying to solve ?

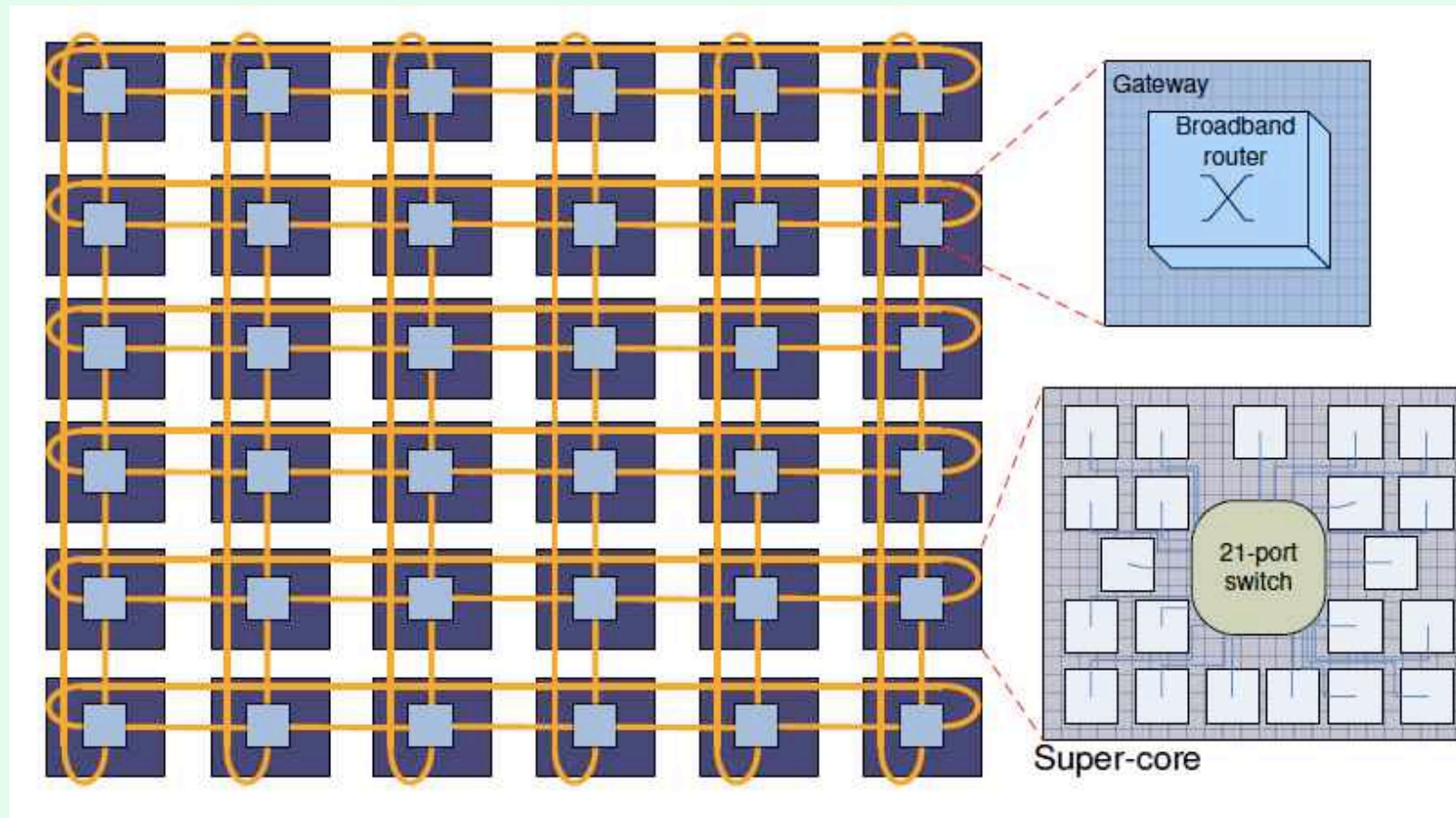


55 W-hour battery
stores the energy of
1/2 a stick of dynamite.

If battery short-circuits,
catastrophe is possible ...

Optical interconnects save energy





Use the photonics layer to shift data in a multicore architecture

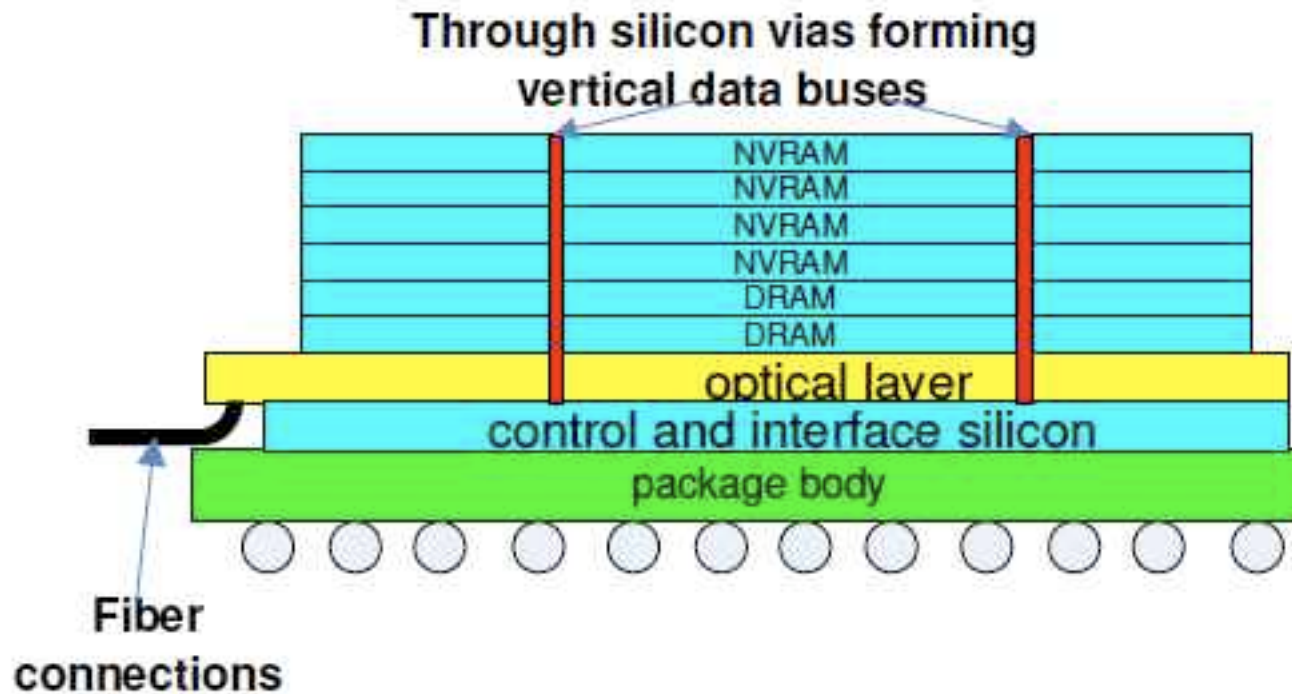


Figure 7.25: A possible optically connected memory stack.

Optical Interconnect: 1.1 TB/s HUB; 1,000,000 links

- 192 GB/s Host Connection
- 336 GB/s to 7 other local nodes in the same drawer
- 240 GB/s to local-remote nodes in the same supernode (4 drawers)
- 320 GB/s to remote nodes
- 40 GB/s to general purpose I/O

Avago microPOD™



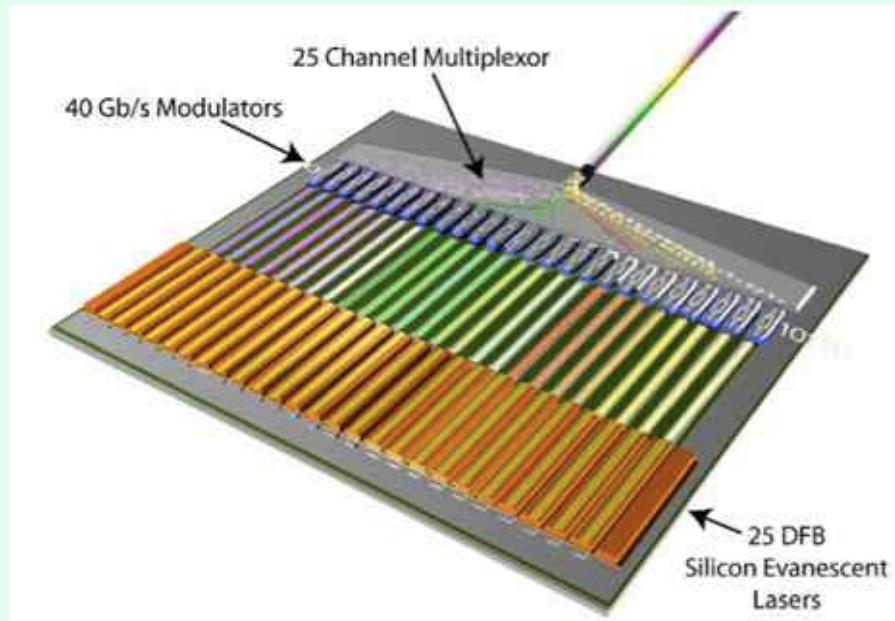
[M. Fields, Avago, OFC 2010, paper OTuP1]

[A. Benner, IBM, OFC 2010, paper OTuH1]

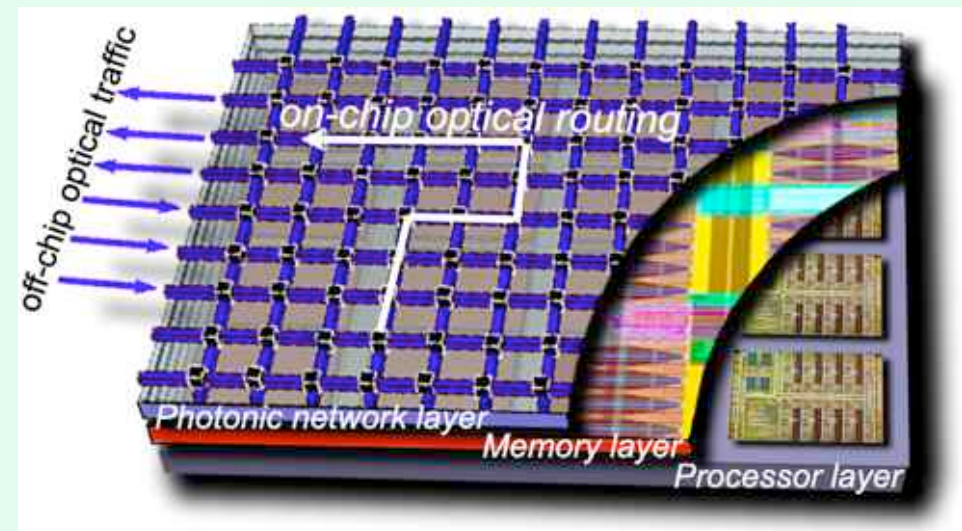
<http://www.ncsa.illinois.edu/BlueWaters/>



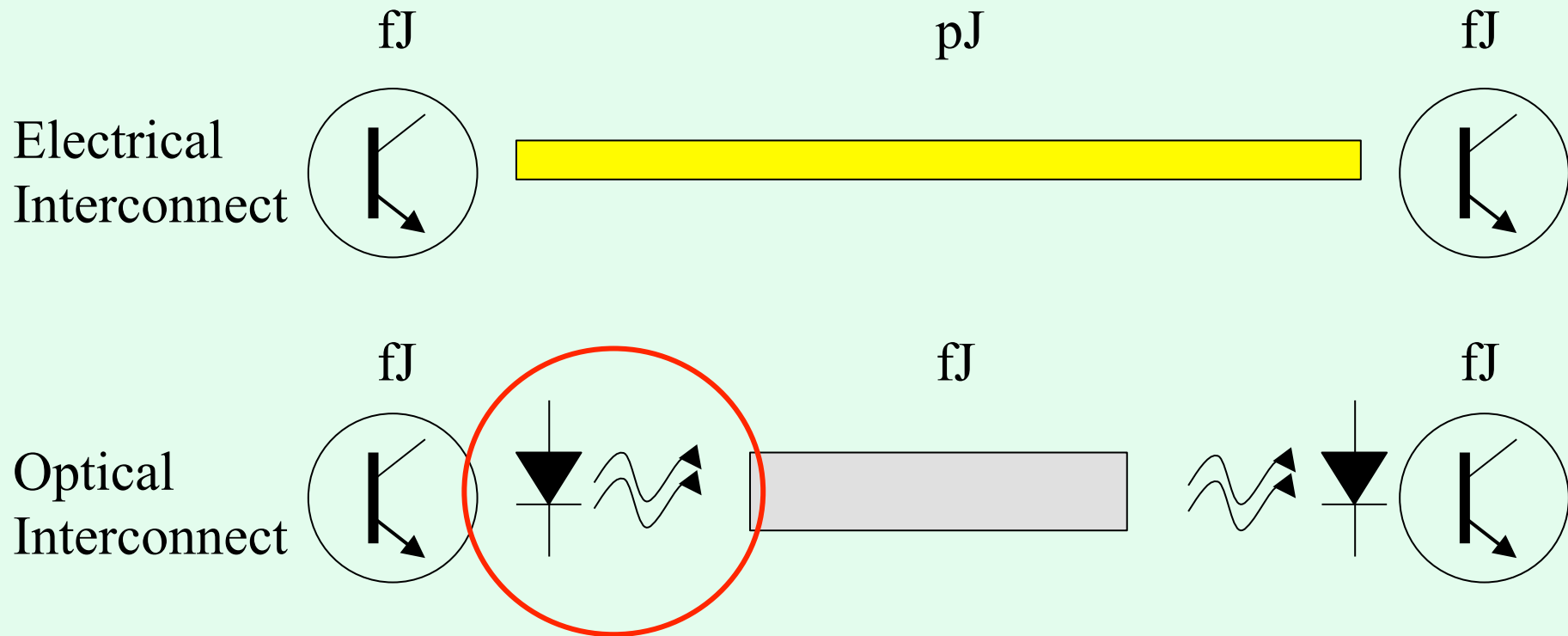
INTEL



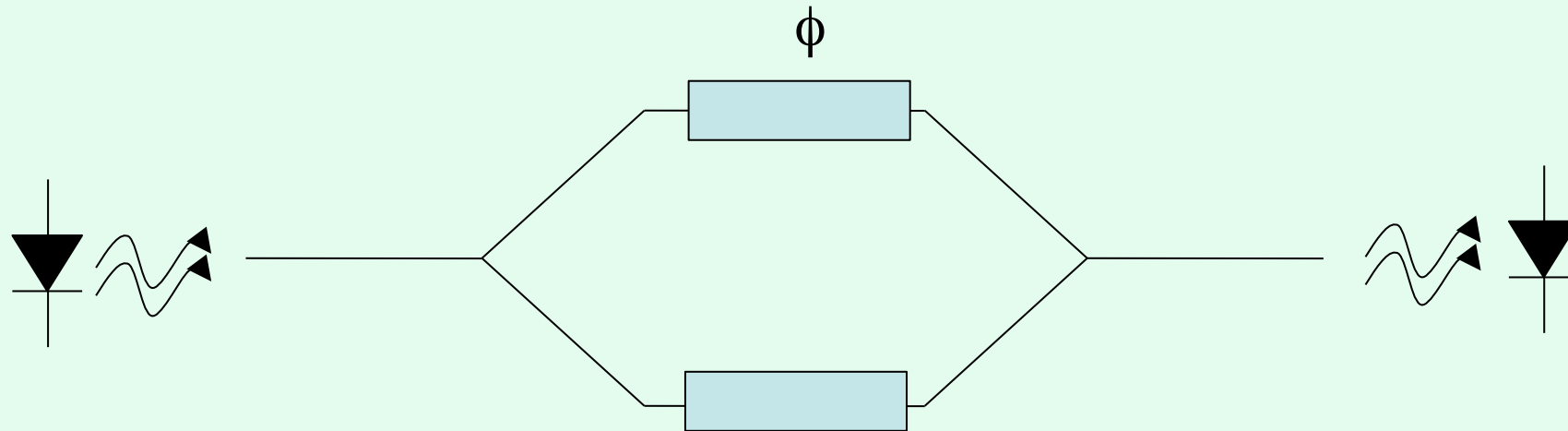
IBM



The idea is to use optical signals to distribute information on-chip, between processors.



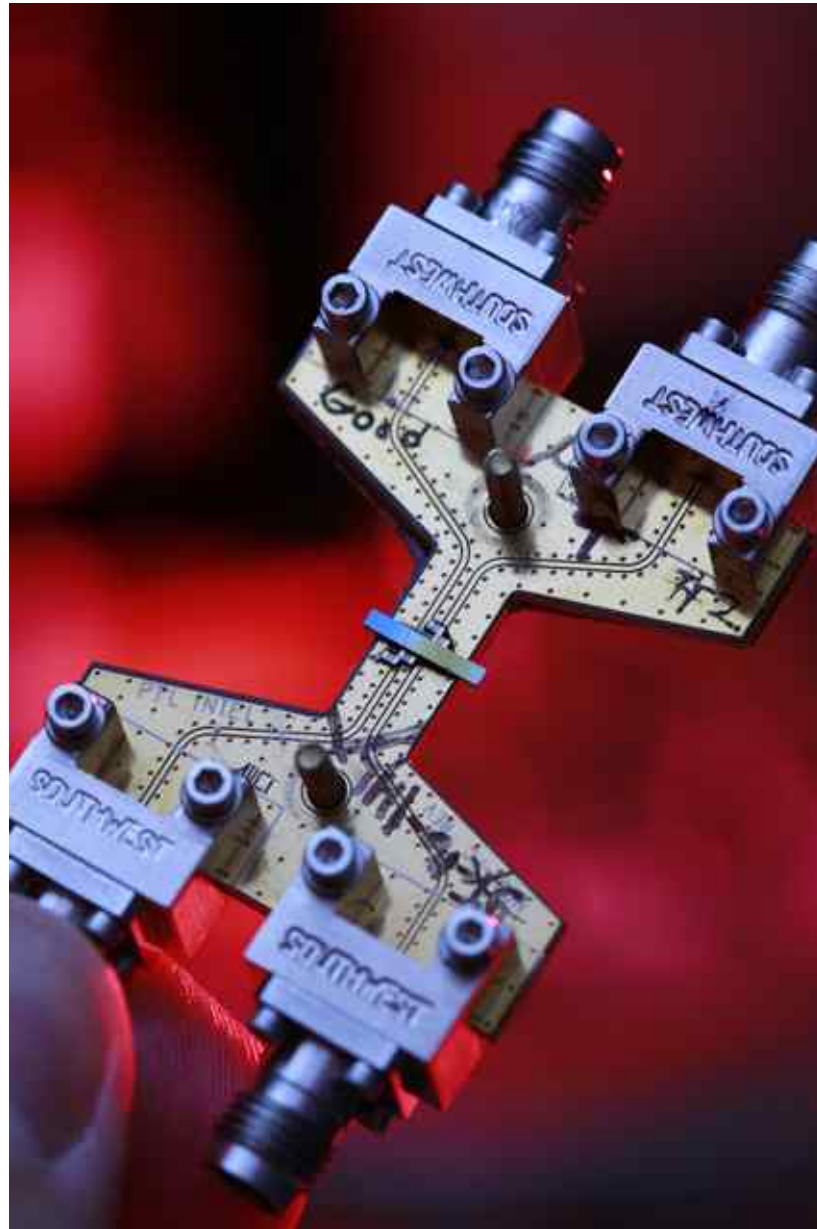
External lightsource + modulator



Requirements: Fast (ideally ps) \Rightarrow Carrier modulation
 \Rightarrow Typical $\Delta n \approx 10^{-4}$
 \Rightarrow Typical length \approx cm

$$\Delta\Phi = \pi$$

$$k_0 \Delta n L = \pi \quad \Rightarrow \quad L = \frac{\lambda}{2\Delta n} \approx 10^4 \lambda$$

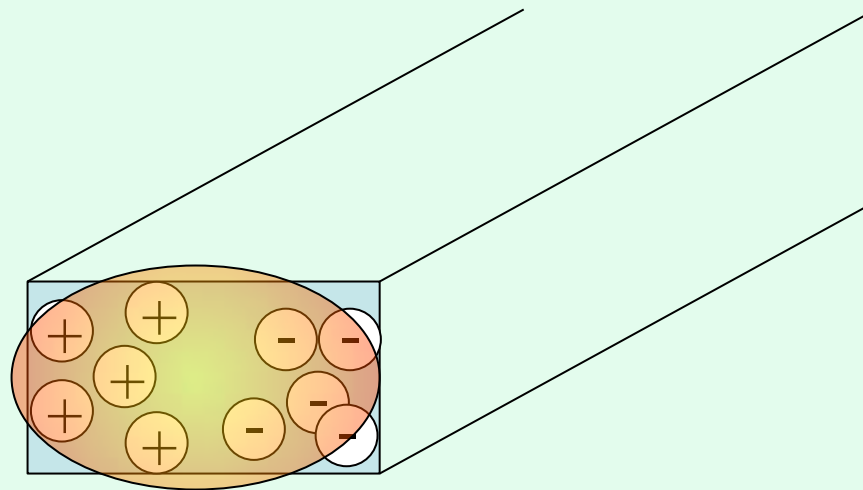


Intel

Solution: Resonant enhancement.

Effective optical path maintained.

Electrical path reduced.

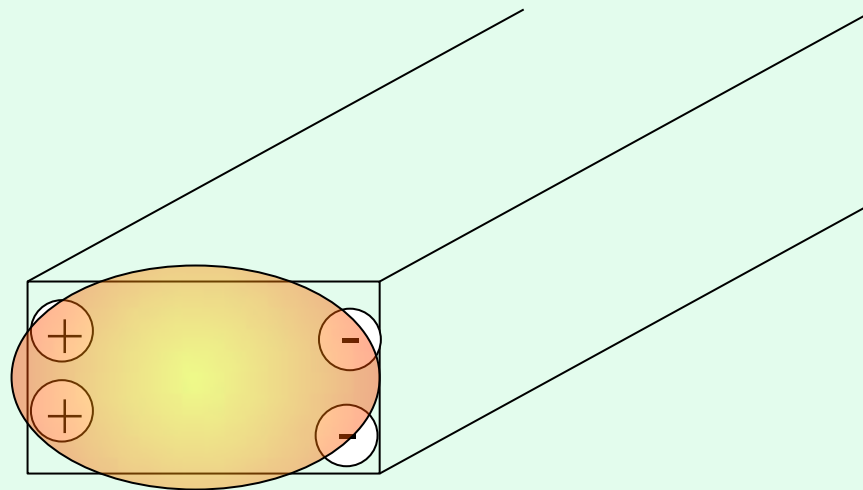


Volume of active carriers reduced.

Solution: Resonant enhancement.

Effective optical path maintained.

Electrical path reduced.



Volume of active carriers reduced



Kotura ring:

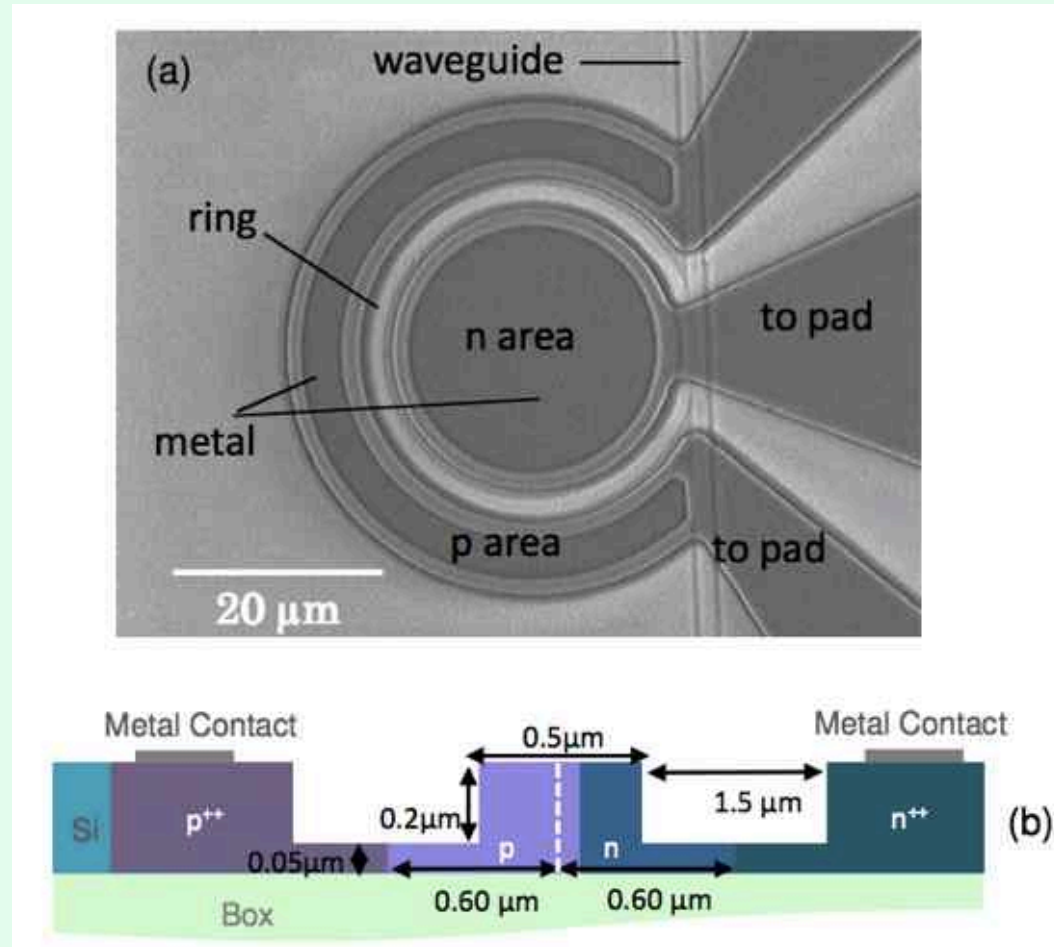
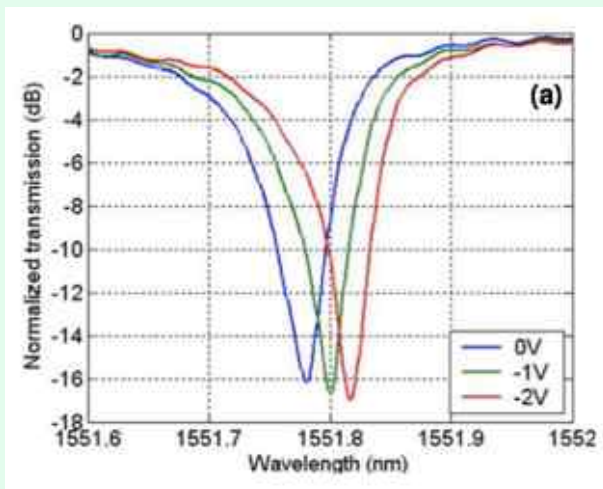
30 μm dia. = 100 μm circumf.

50 fJ/bit

10 GHz bandwidth

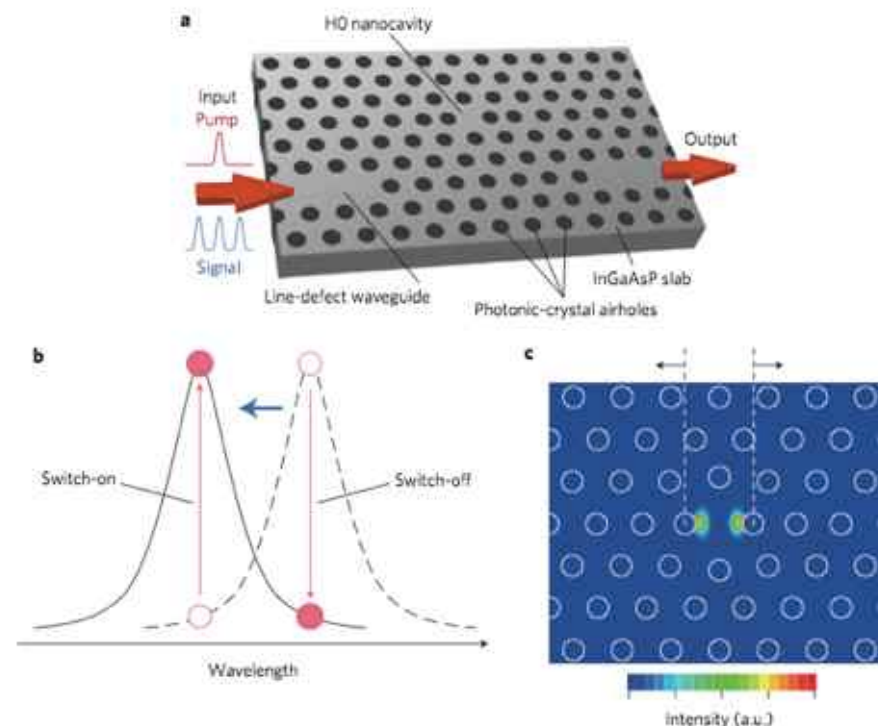
Tuning energy: > 100 fJ/bit

Tolerances ?

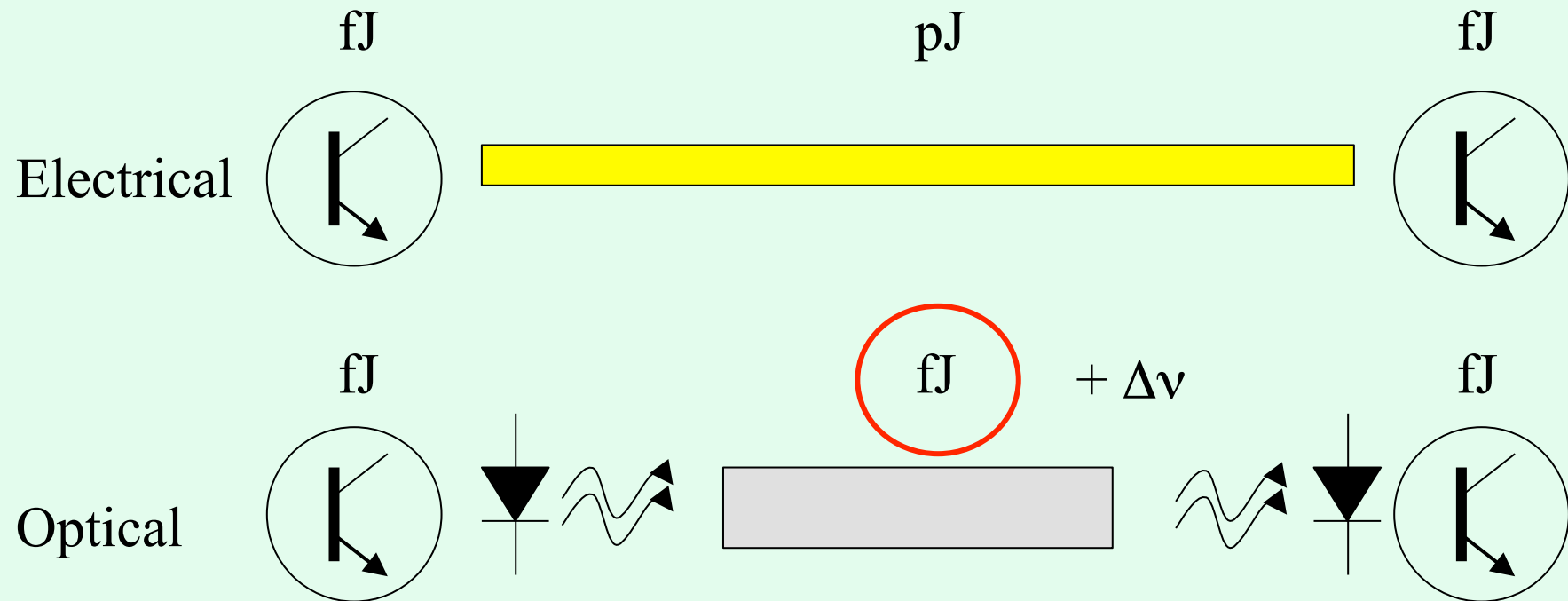


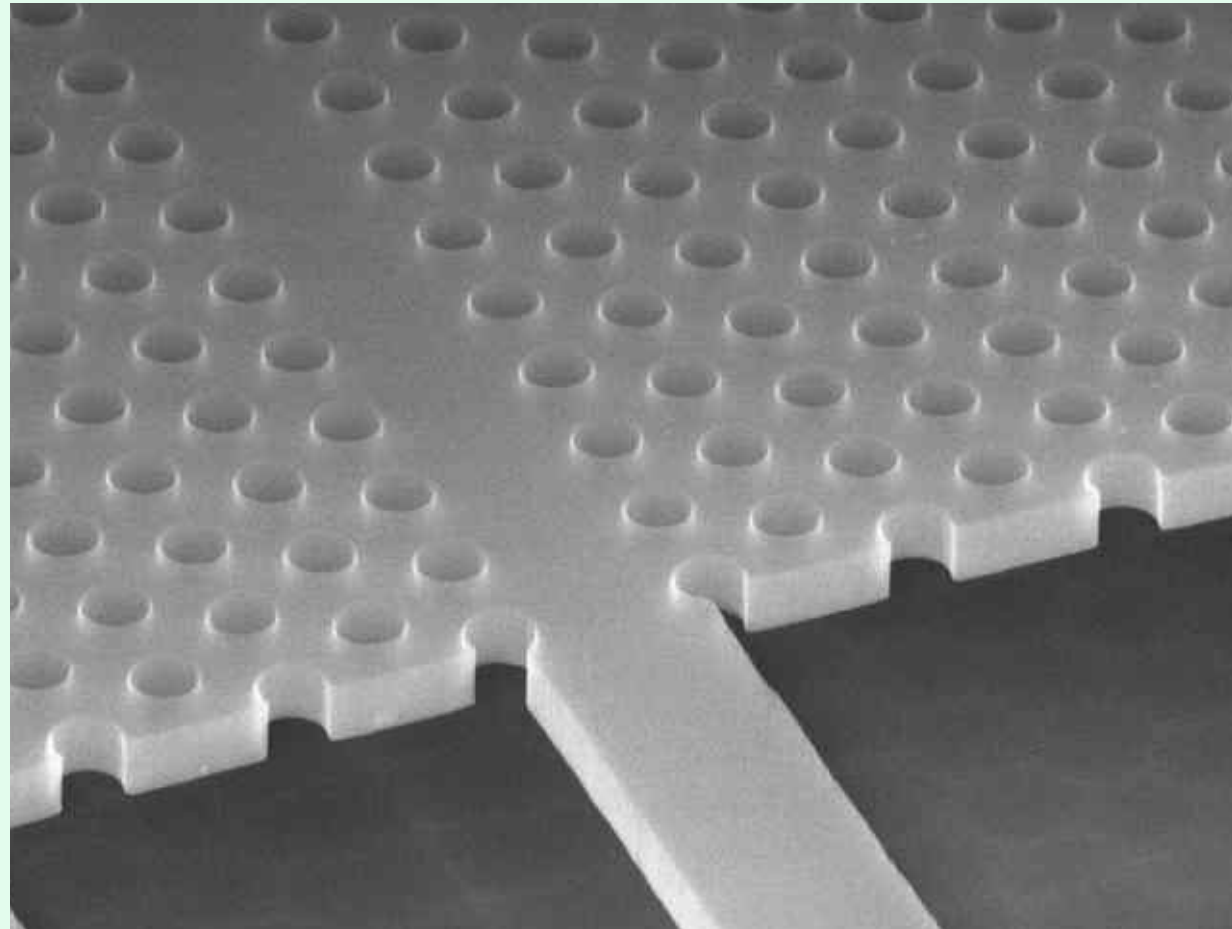
Sub-femtojoule all-optical switching using a photonic-crystal nanocavity

Kengo Nozaki^{1*}, Takasumi Tanabe^{1,2}, Akihiko Shinya^{1,2}, Shinji Matsuo³, Tomonari Sato³, Hideaki Taniyama^{1,2} and Masaya Notomi^{1,2*}

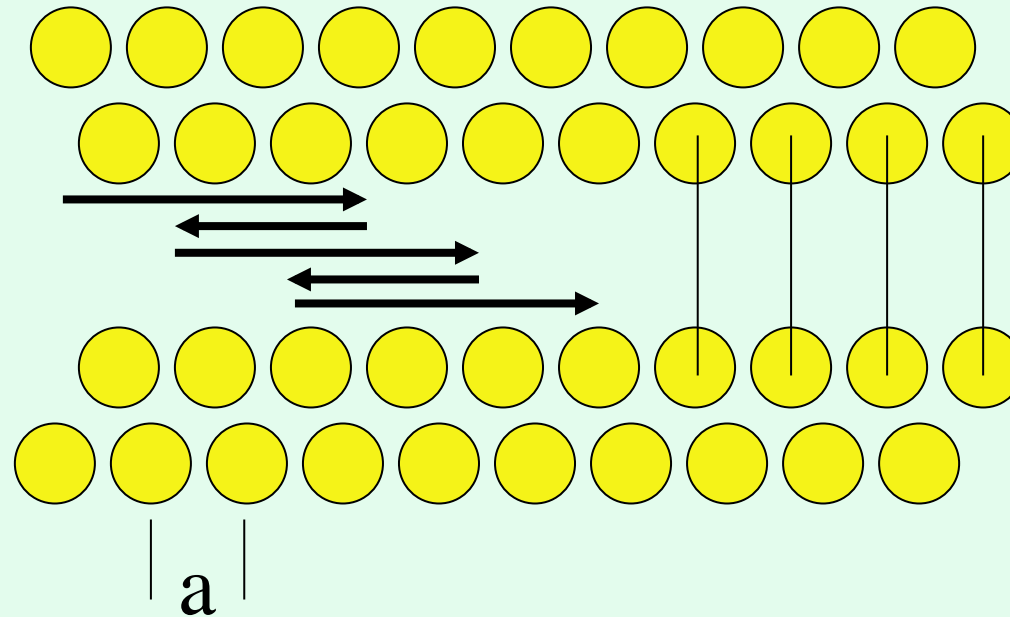


Optical interconnects save energy



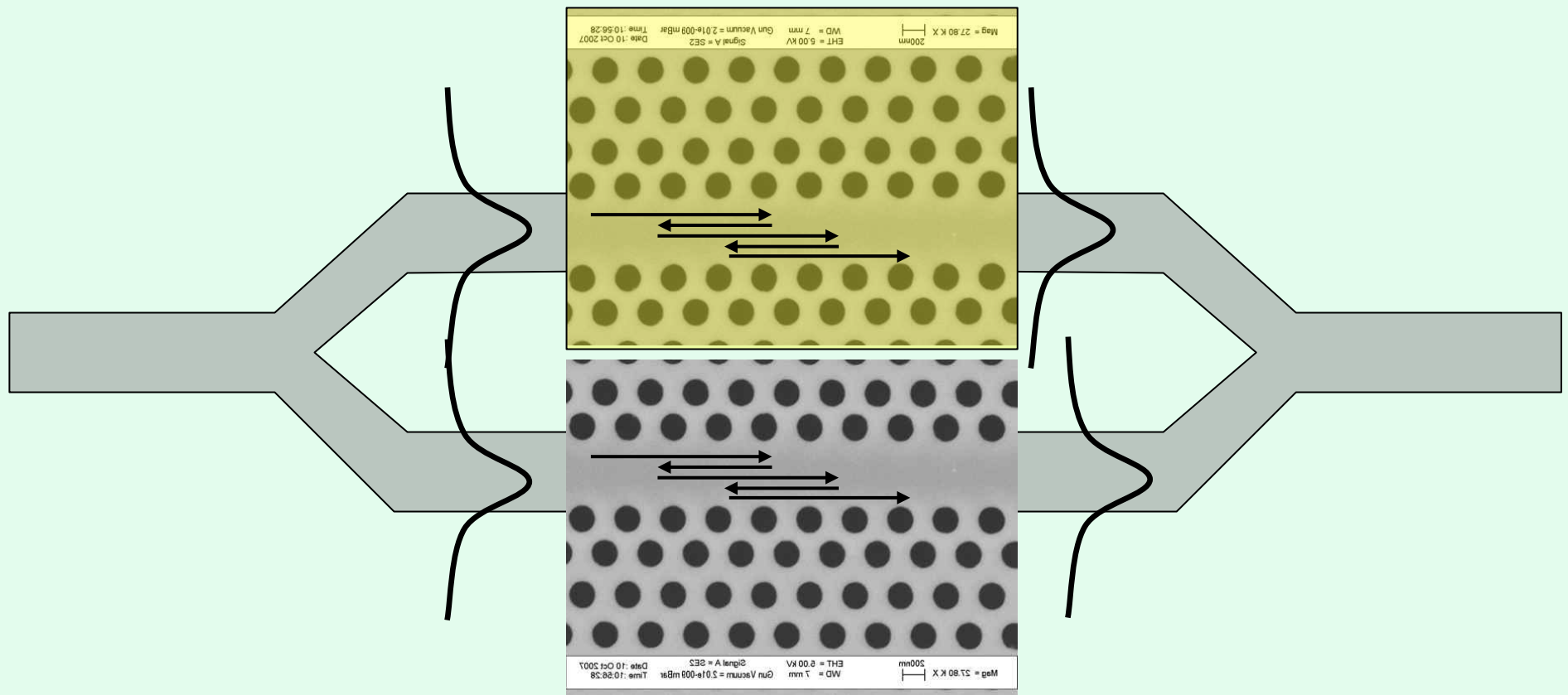


220 nm Si waveguide, airbridge or oxide clad

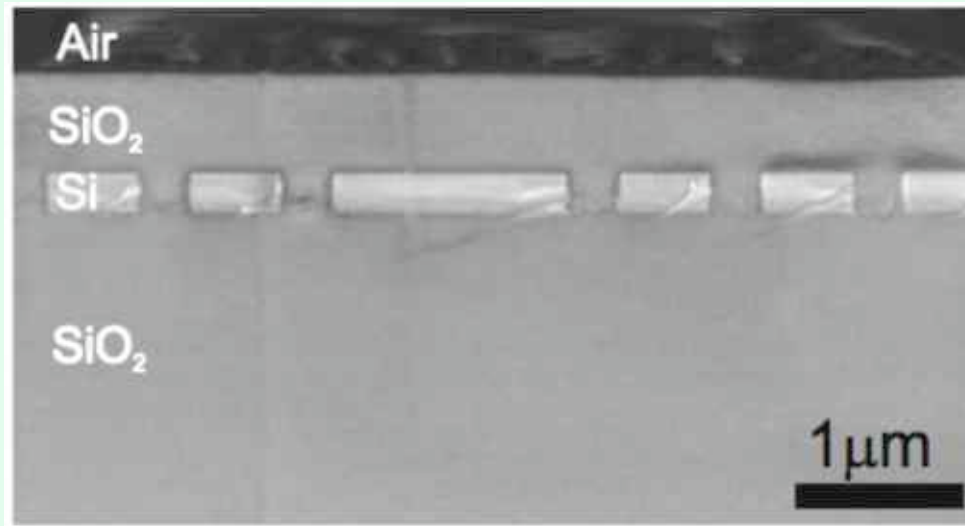
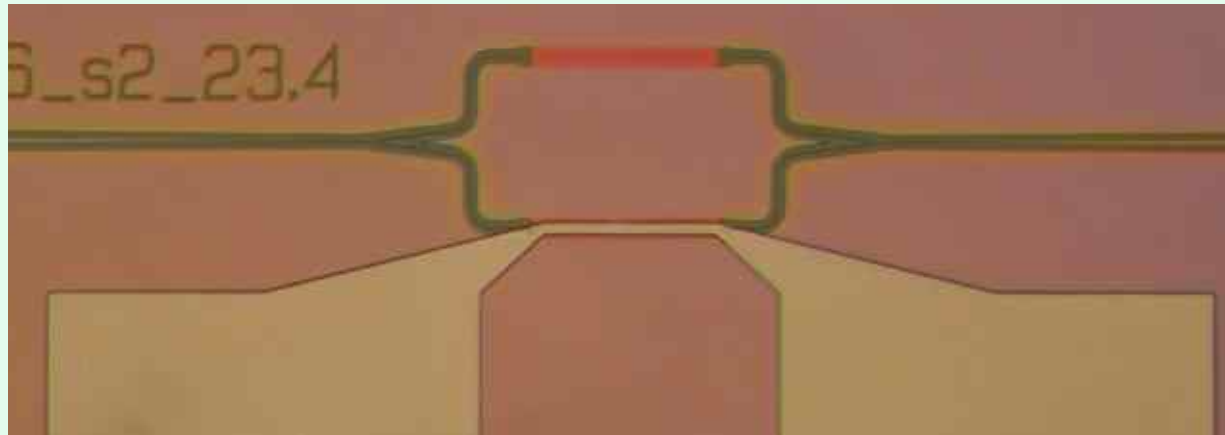


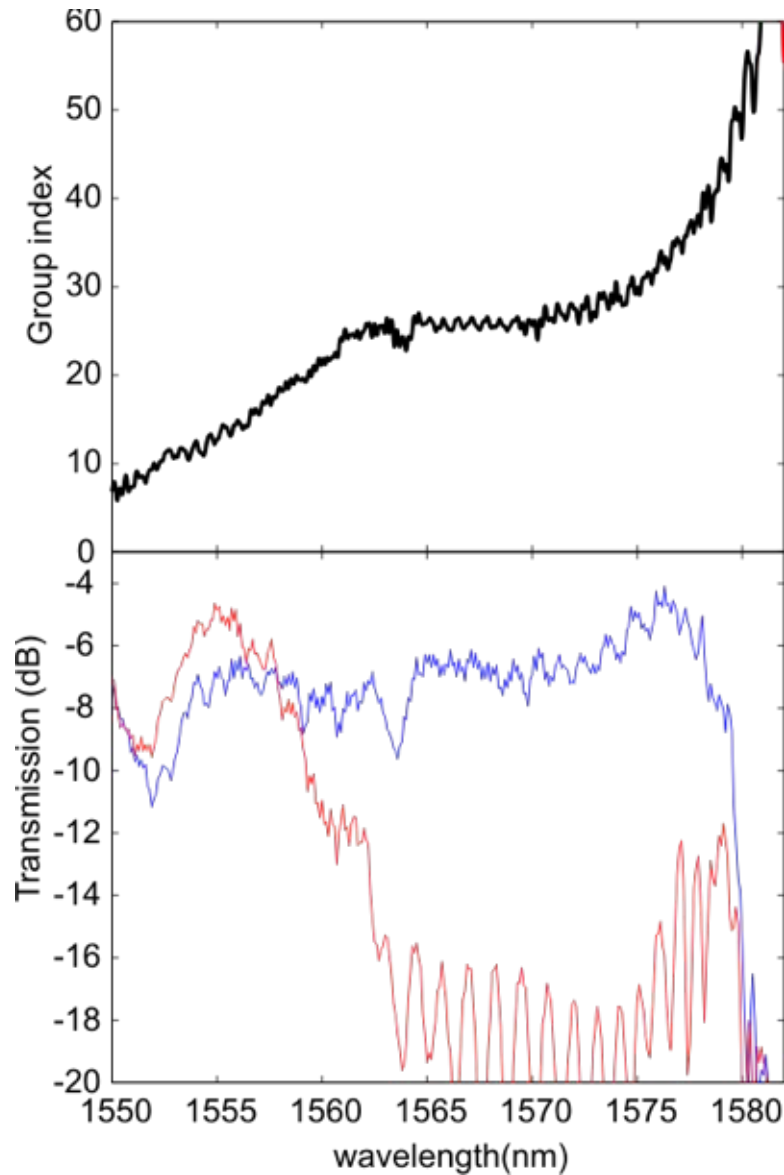
In the slow light regime, one can imagine the mode taking a longer route - that's why it takes more time, and why there is more light inside the structure.

PhC MZI modulator



80 μm long PhC



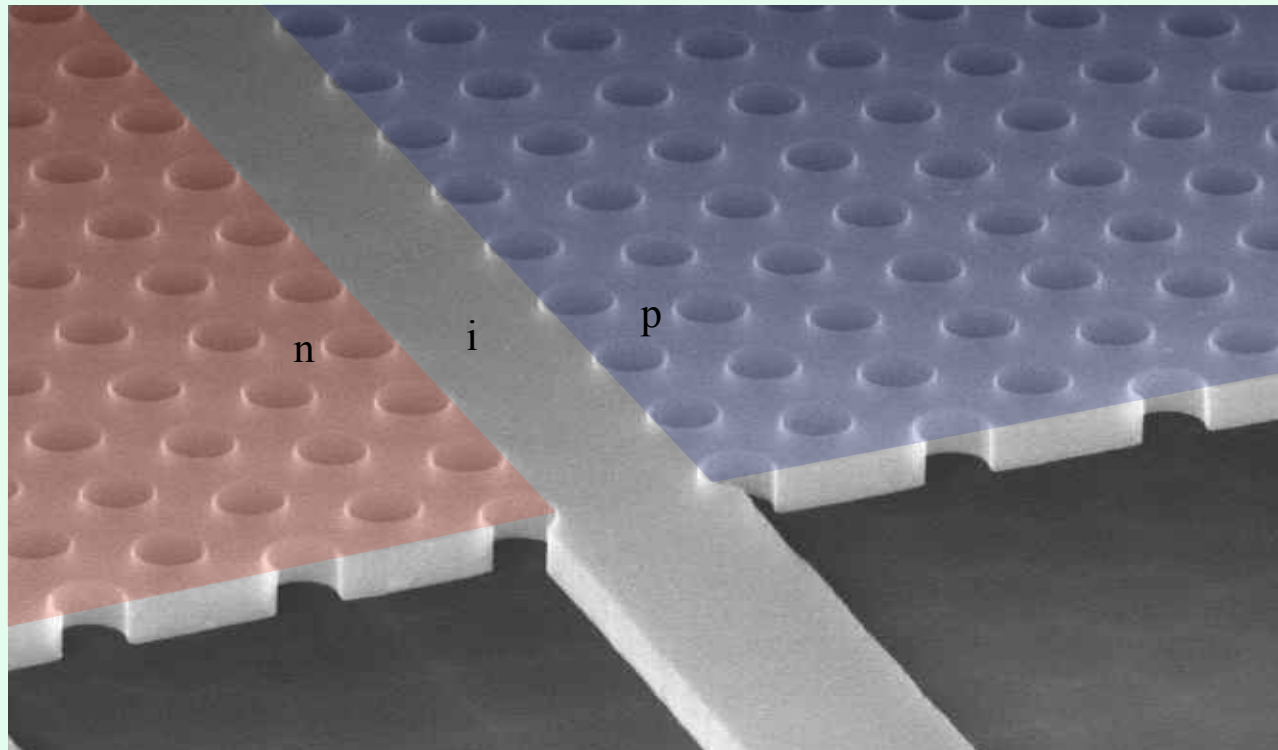


Dispersion curve

Switching performance

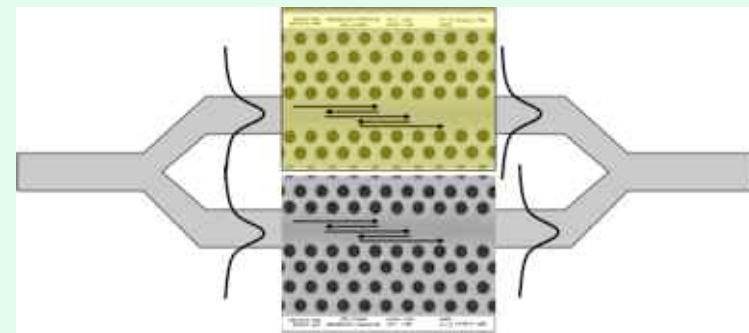
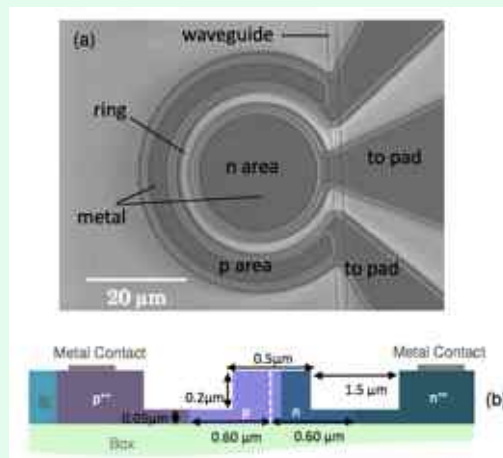
William Whelan-Curtin Kapil Debnath

Electrical operation. Work in progress.....

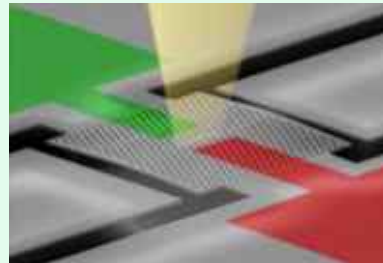
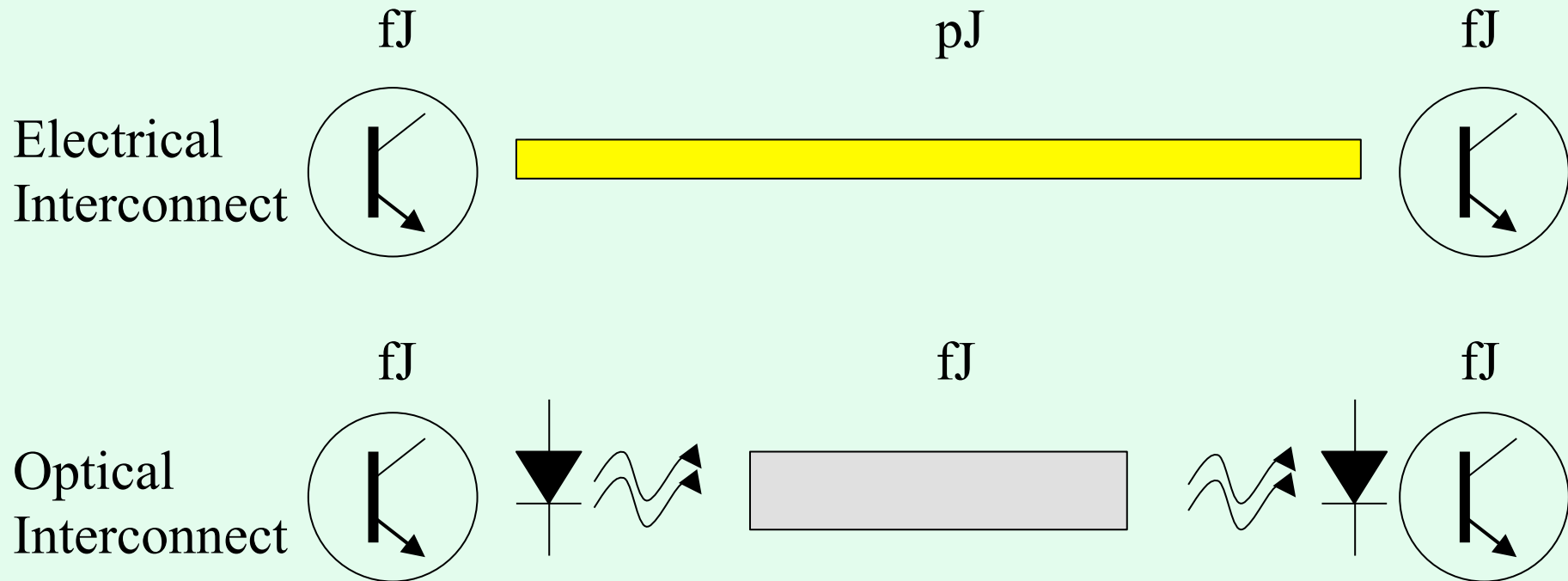


The slow light concept allows us to make small footprint, low driving power modulators with high bandwidth.

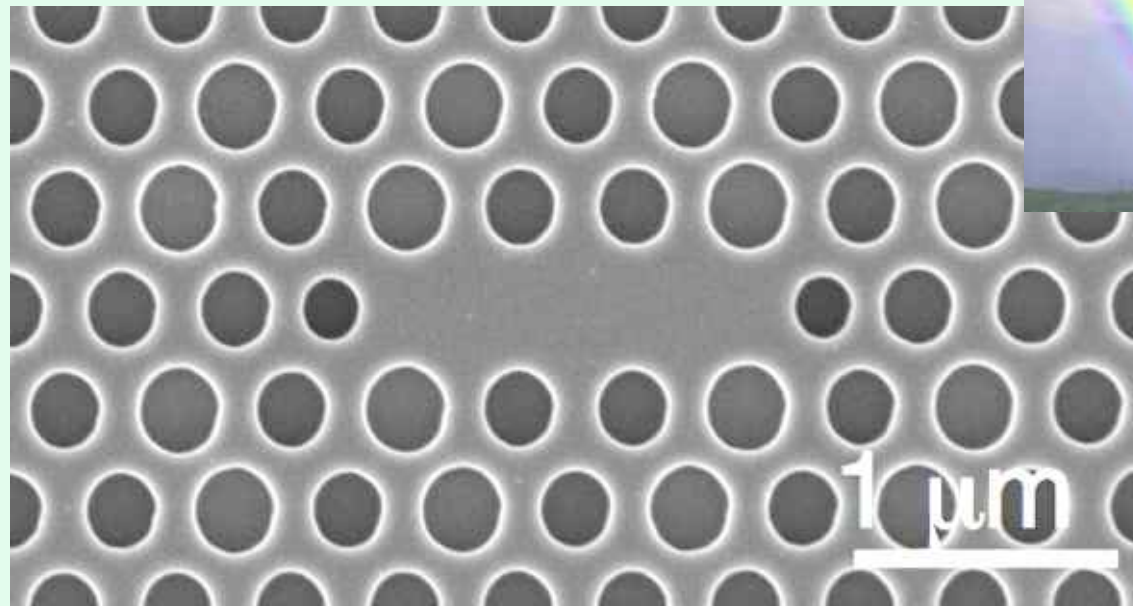
They are of similar size, and therefore capacitance, as State-of-the-Art microring resonators, but offer far more bandwidth and do not need to be tuned.

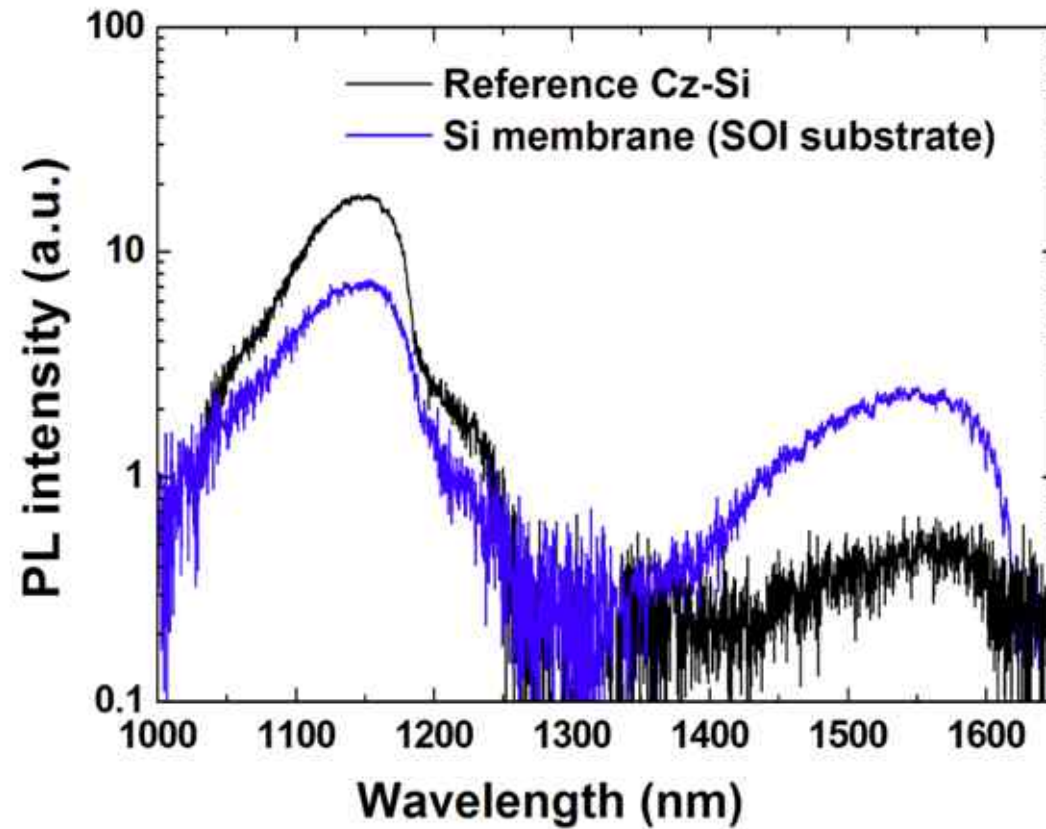


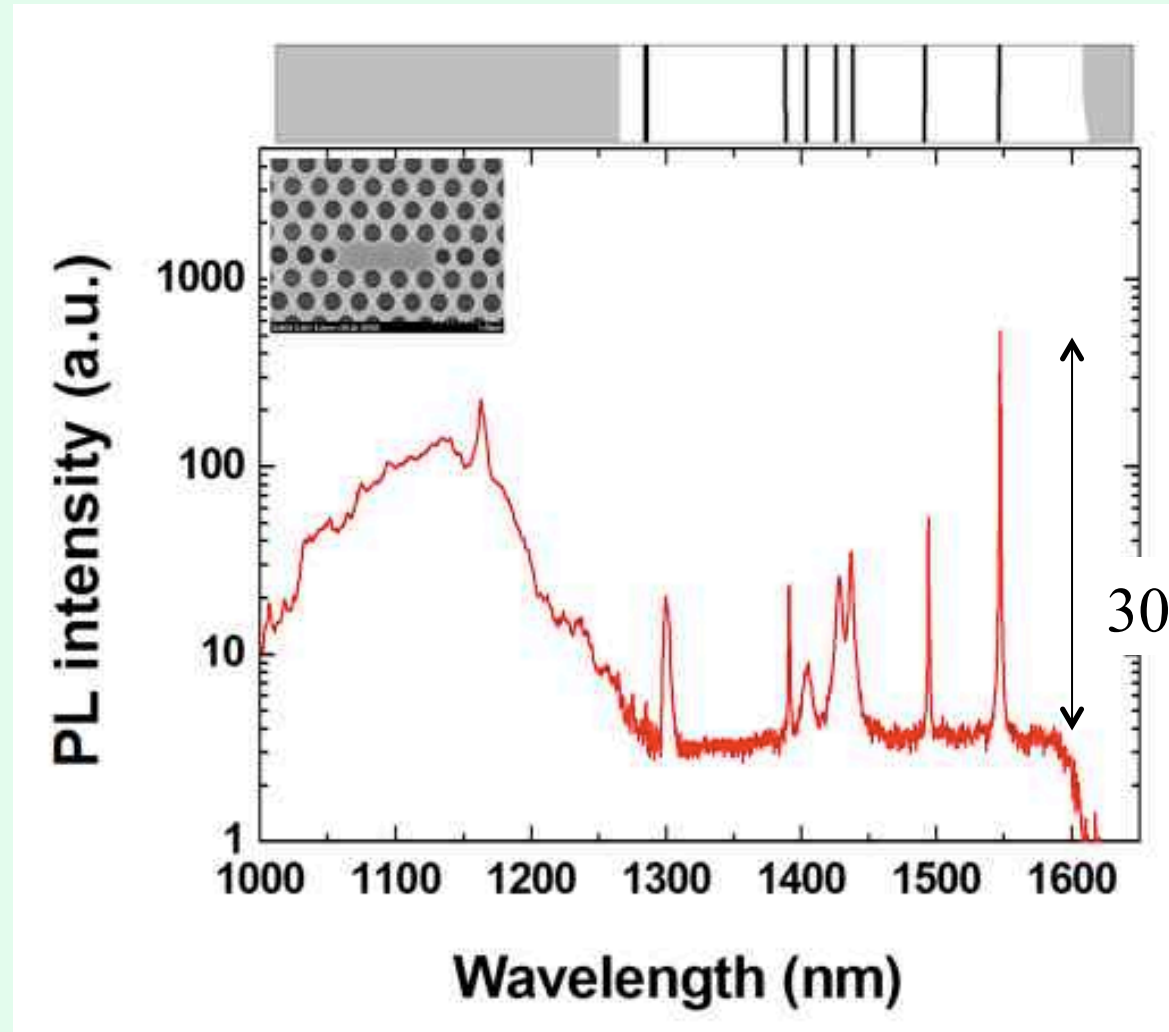
2. Solution: Internal lightsource



Defect luminescence







300x enhancement !!

Why 300x ?

- a) Purcell effect
- b) Extraction efficiency

“Room-temperature emission at telecom wavelengths from silicon photonic crystal nanocavities”,
R. Lo Savio et al., Appl. Phys. Lett. 2011



Photonics

The Vs and Qs of optical microcavities

Pauline Rigby and Thomas F. Krauss

Nature News & Views, 1997

$$F_P = \frac{3\lambda^3}{4\pi^2} \frac{Q}{V}$$

$$\eta_{rad} = \frac{\tau_{nonrad}}{\frac{\tau_{rad}}{F_P} + \tau_{nonrad}}$$

E. M. Purcell, Phys. Rev. 69, 37 (1946).



$$T_{i \rightarrow f} = \frac{2\pi}{\hbar} \left| \langle f | H' | i \rangle \right|^2 \rho$$

↑
Matrix element

↙
Density of states

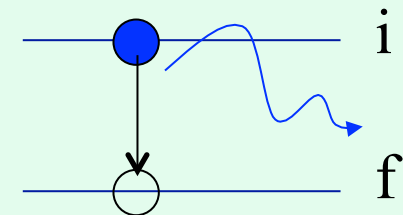
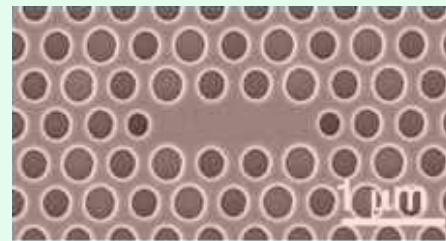
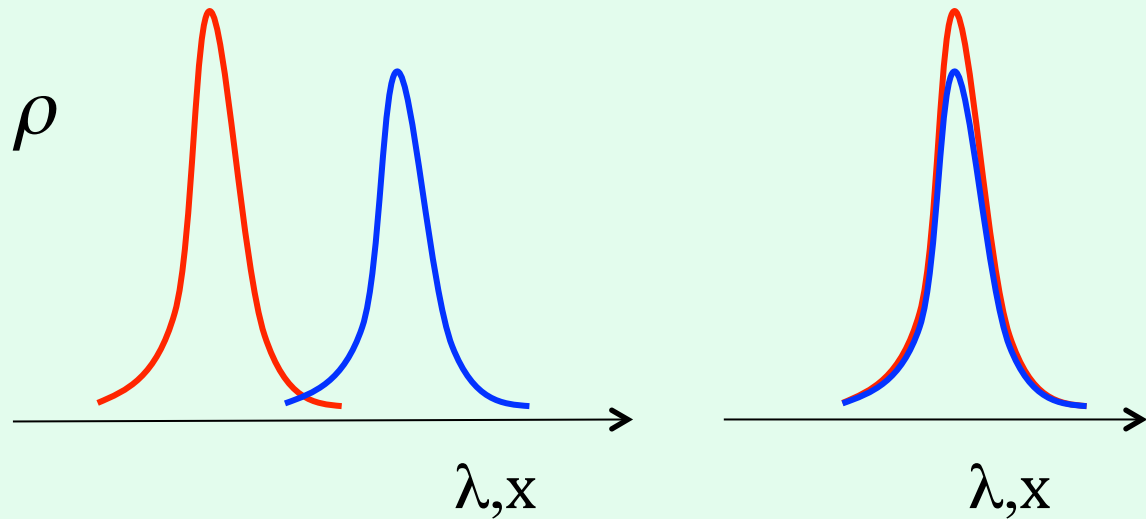
The Purcell factor relates to Fermi's Golden Rule

The transition between two quantum mechanical states is given by the product of the matrix element (derived from the Hamiltonian) and the density of final states.

This transition probability is also called decay probability and is related to mean lifetime.

$$T_{i \rightarrow f} = \frac{2\pi}{\hbar} \left| \langle f | H' | i \rangle \right|^2 \rho$$

$$F_P = \frac{3\lambda^3}{4\pi^2} \frac{Q}{V}$$



To enhance the interaction between a cavity and an emitter, they need to agree in emission wavelength and be in the same space $\rightarrow Q/V$

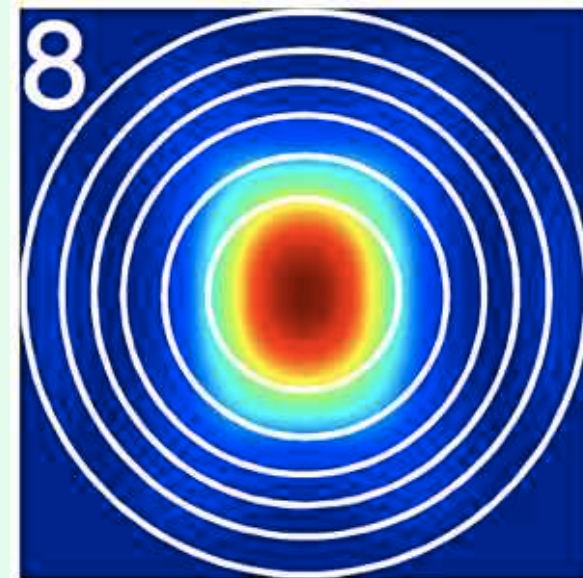
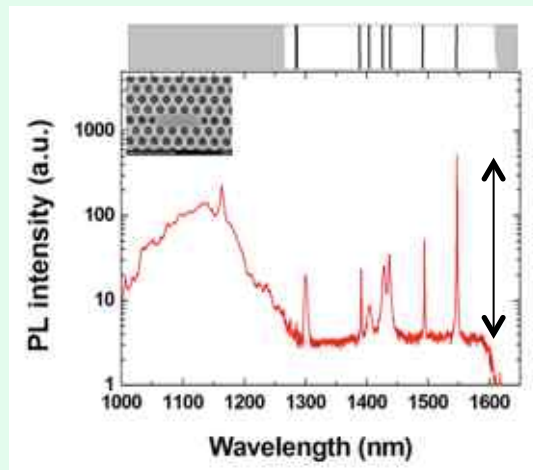
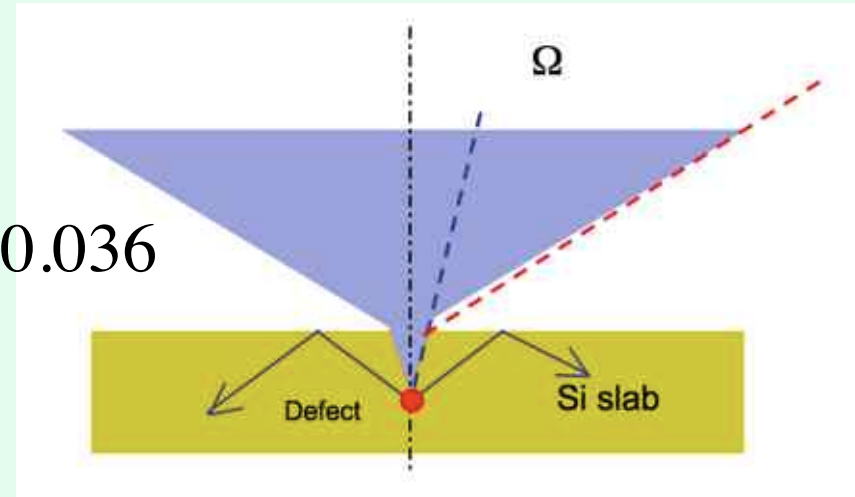
$$F_p = \frac{\gamma}{\eta_{cavity} \eta_{membrane}}$$

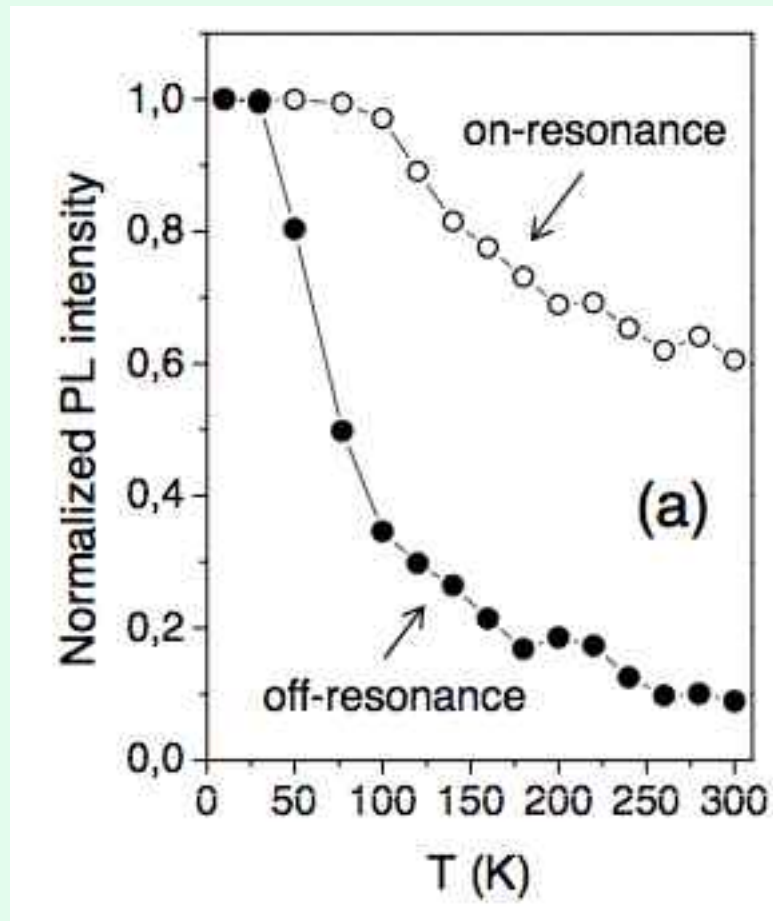
$$\eta_{membrane} = 0.036$$

$$F_p = 12, \quad \eta_{ext} = 25$$

$$\eta_{cavity} = 0.9$$

$$\gamma = 300$$



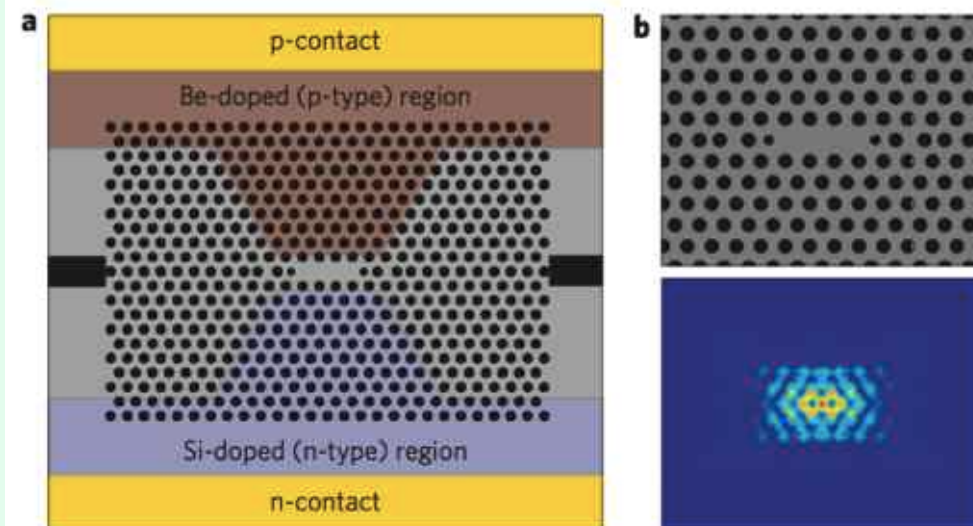
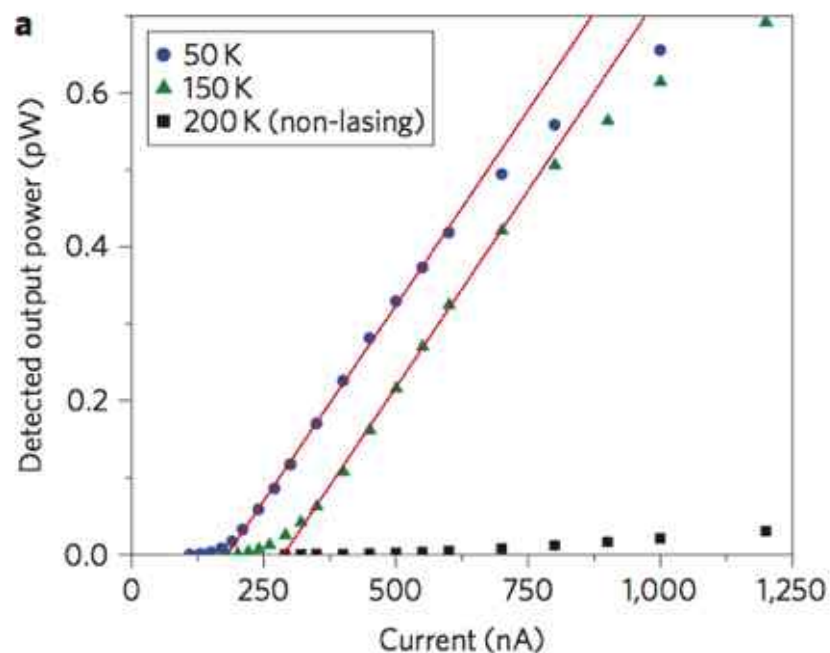


$$\eta_{rad} = \frac{\tau_{nonrad}}{\frac{\tau_{rad}}{F_P} + \tau_{nonrad}}$$

The Purcell-factor makes defect emission “Room-temperatureable”

Ultralow-threshold electrically pumped quantum-dot photonic-crystal nanocavity laser

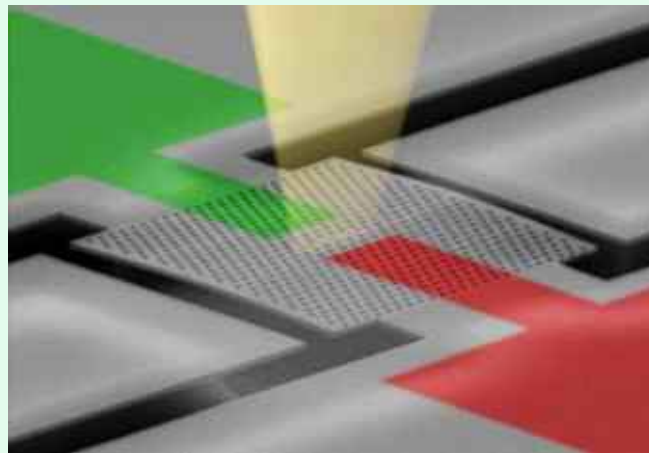
Bryan Ellis¹, Marie A. Mayer^{2,3}, Gary Shambat¹, Tomas Sarmiento¹, James Harris¹, Eugene E. Haller^{2,3} and Jelena Vučković^{1*}





Using hydrogen treatment and well-designed photonic crystal cavities, we can achieve significant light emission directly from silicon. This is not yet sufficient for optical interconnects, but further improvements are possible.

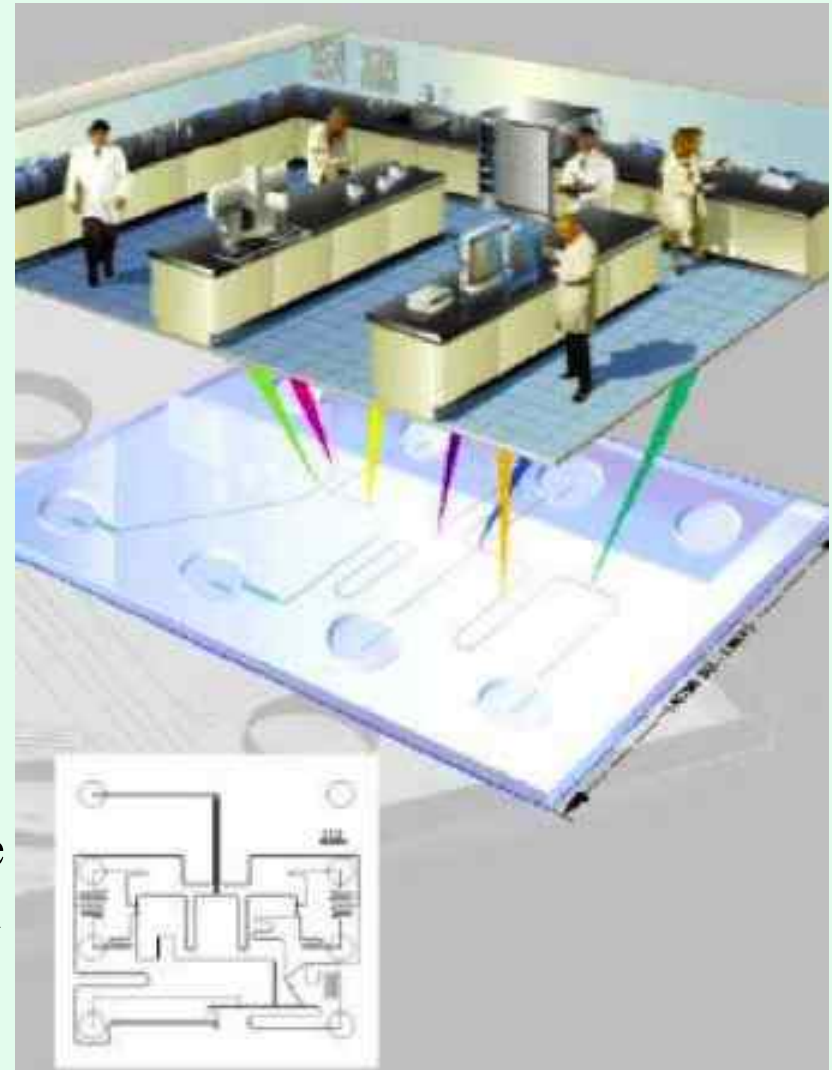
The output power is competitive with comparable III-V devices, although not with III-V materials as such.

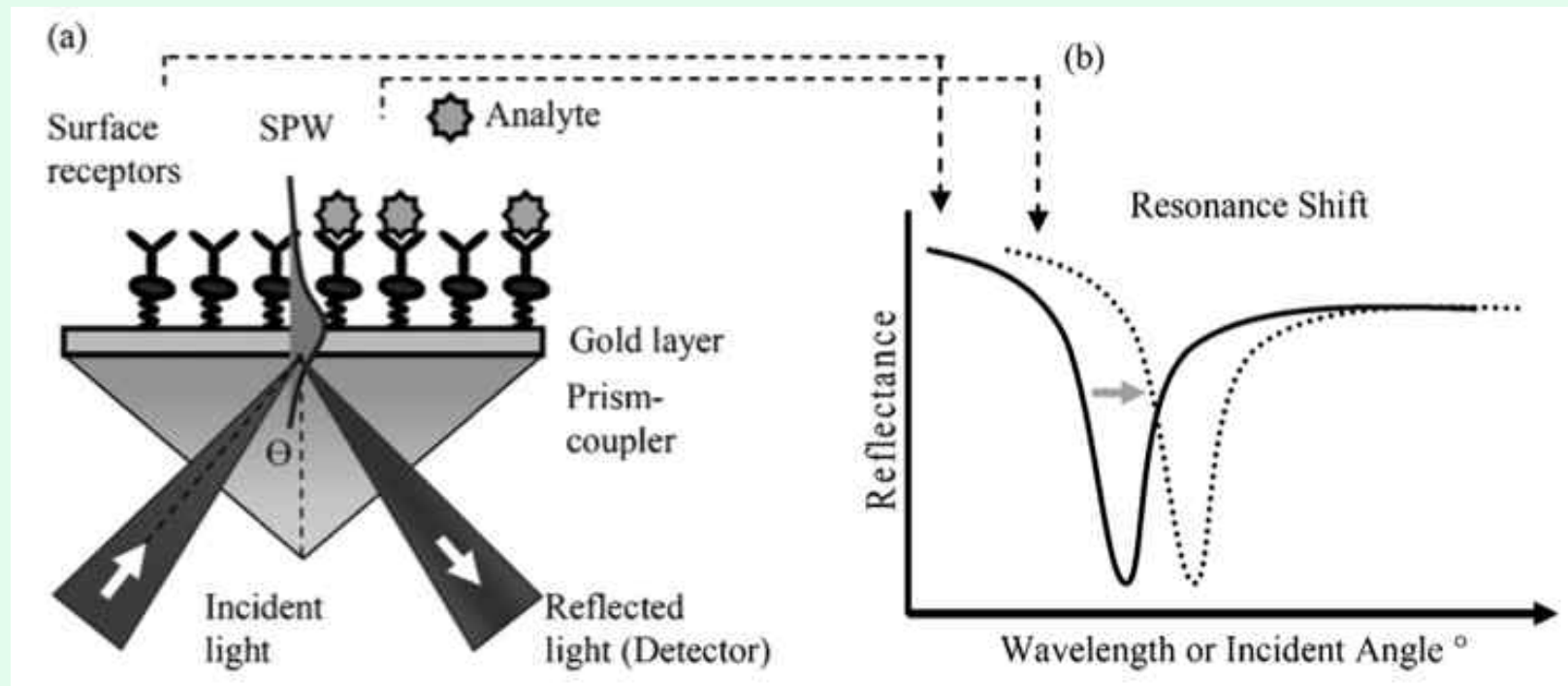


2. Silicon Nanophotonics for Biosensors

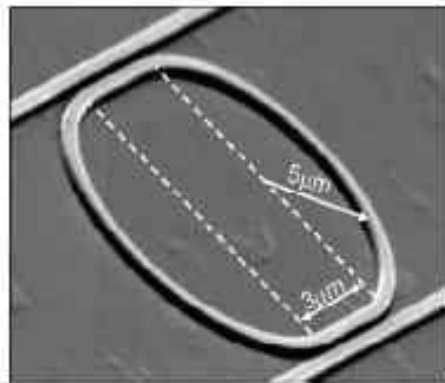


The Lab on a chip (LoC) concept aims to realise biochemical analysis/synthesis in a miniaturised format.

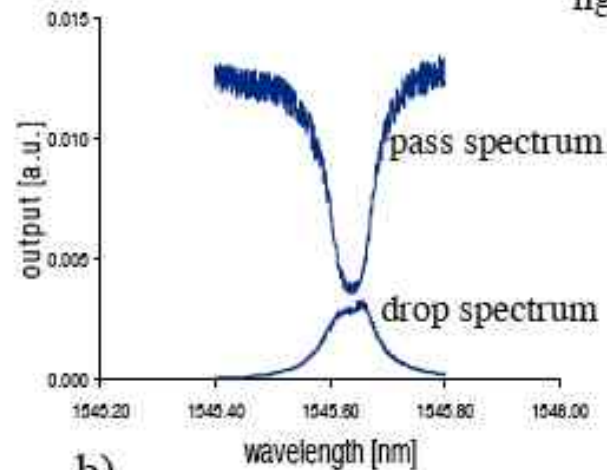




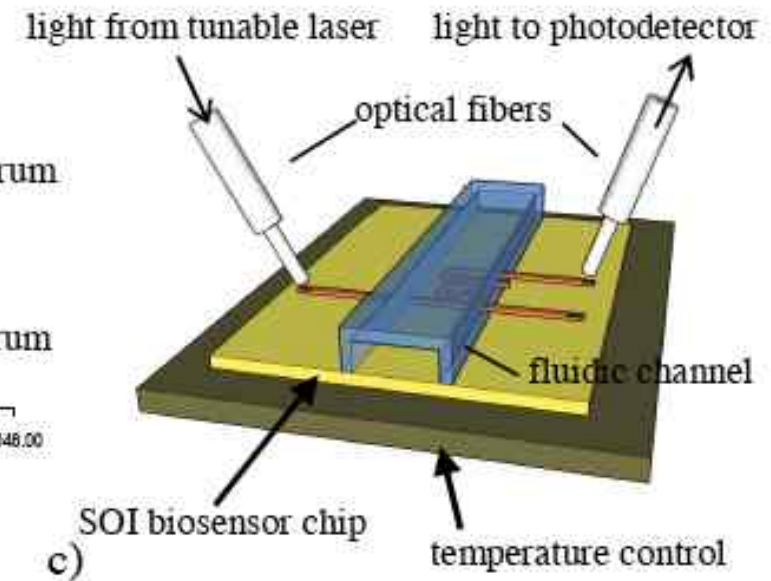
Very high sensitivity -> Biacore
Broad resonance



a)

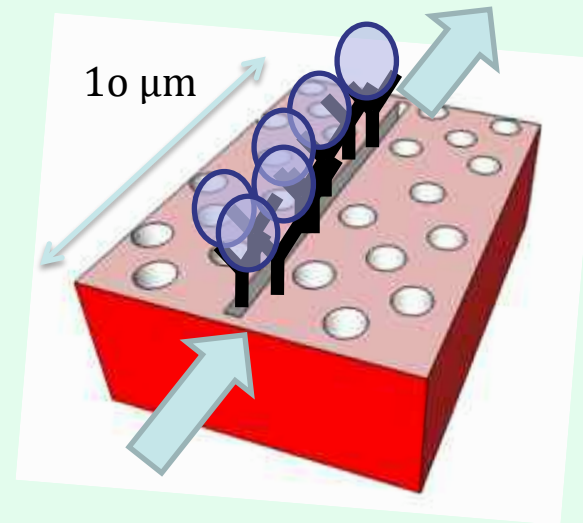
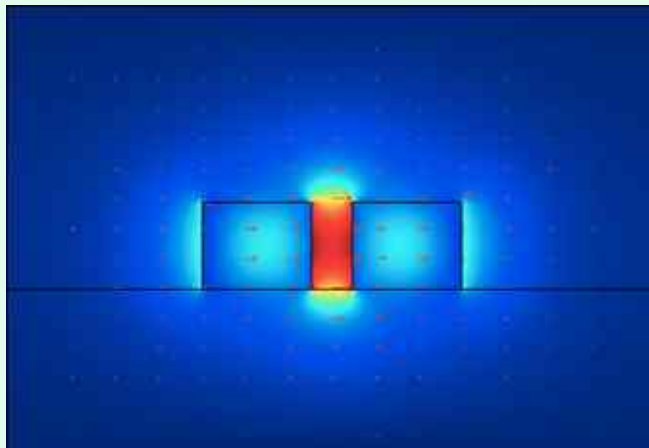


b)

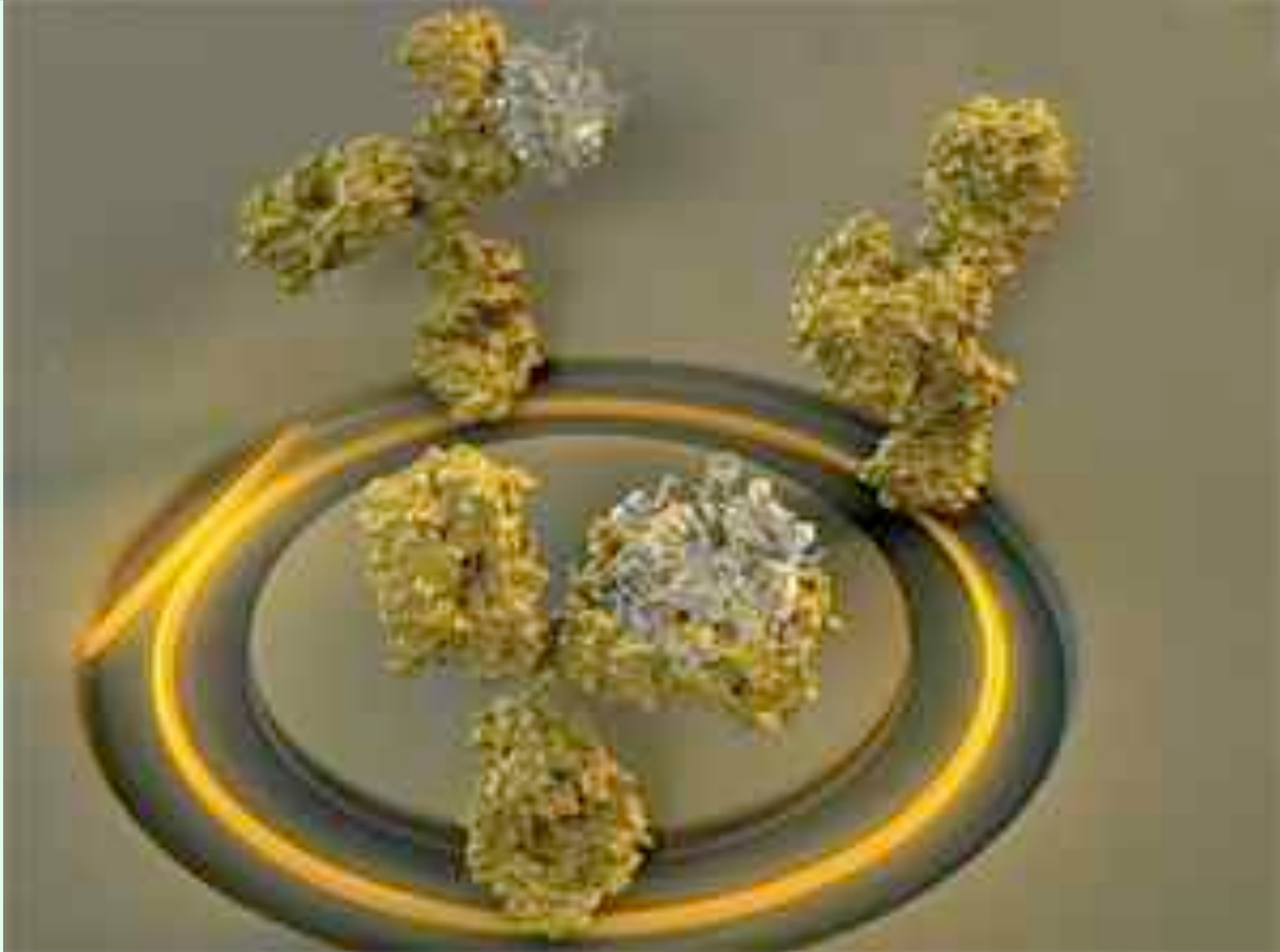


c)

Lower sensitivity
Narrow resonance -> Genalyte

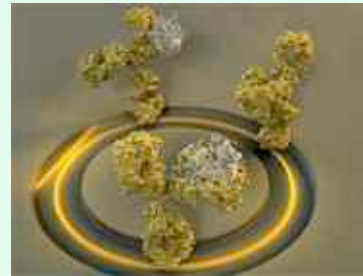


High sensitivity
Narrow resonance -> ???





Light source

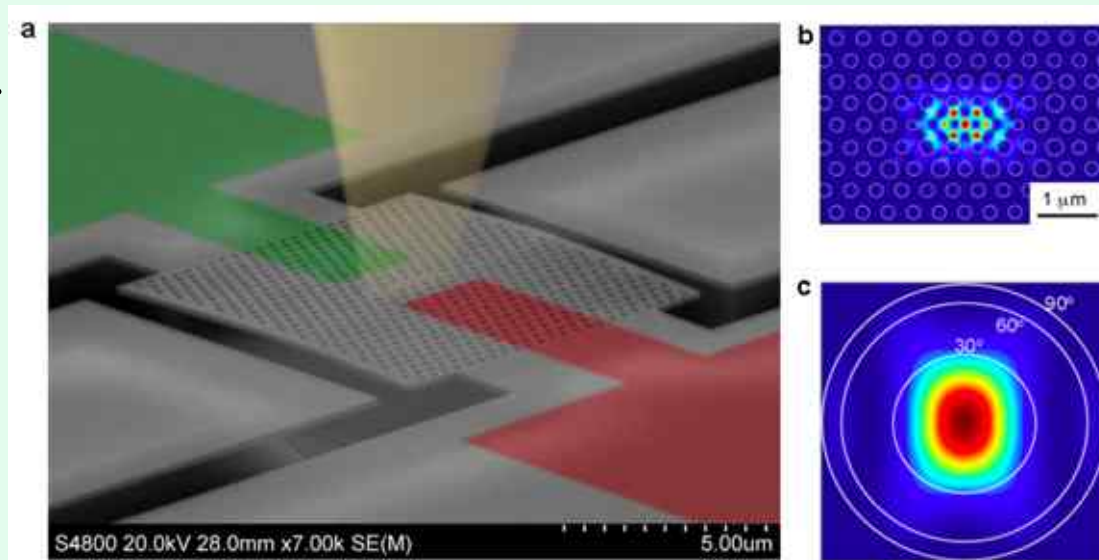
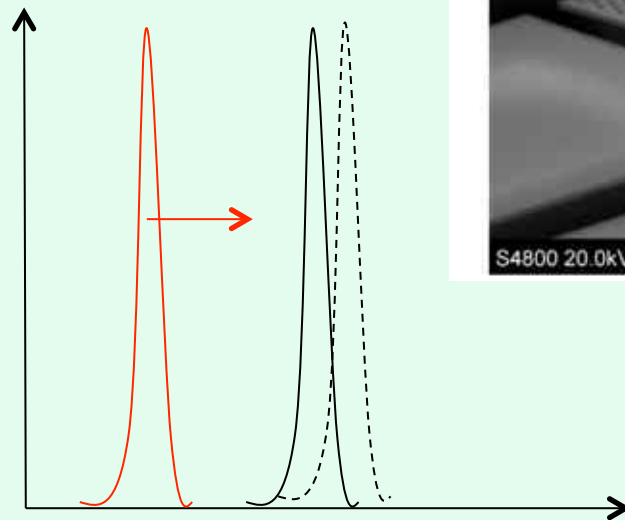


Spectrum Analyser



Transducer

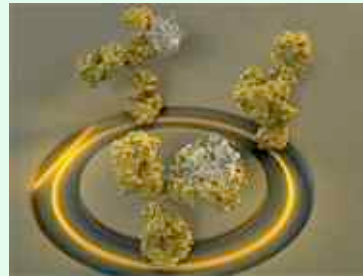
Source



The possible integration of silicon light sources would lead to miniaturisation, large scale integration and simplicity.



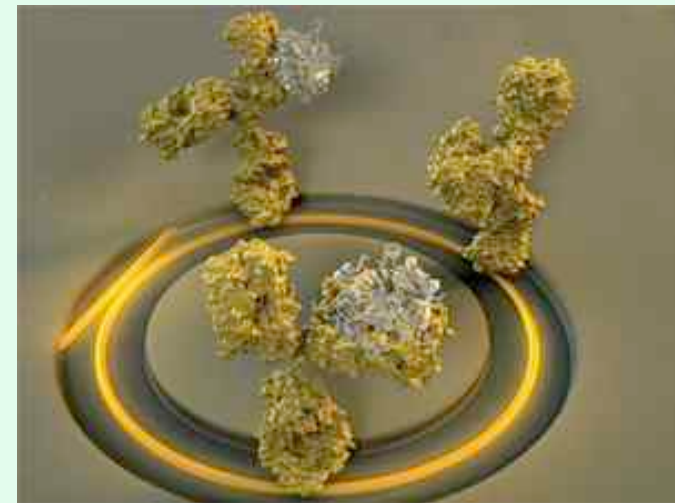
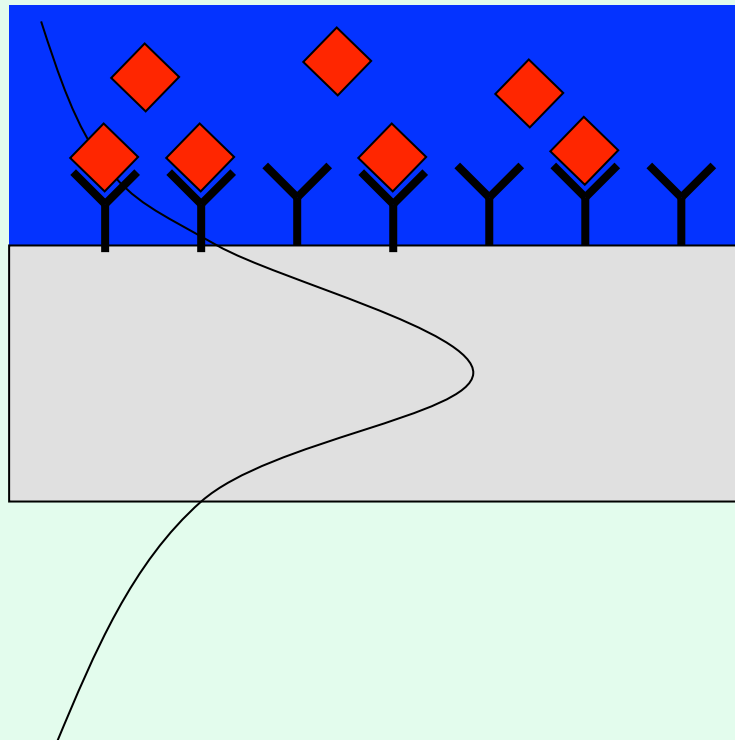
Light source



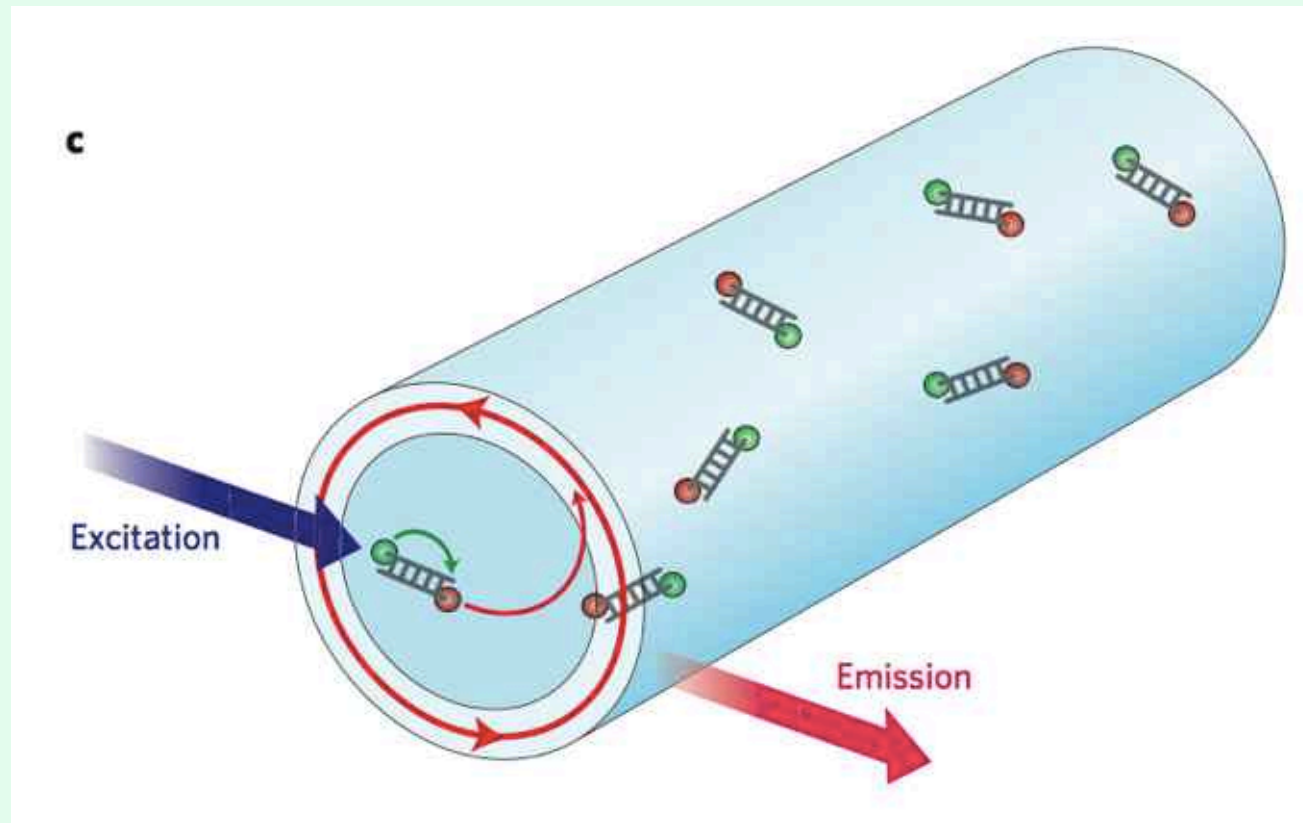
Spectrum Analyser



2nd problem: Diffusion time

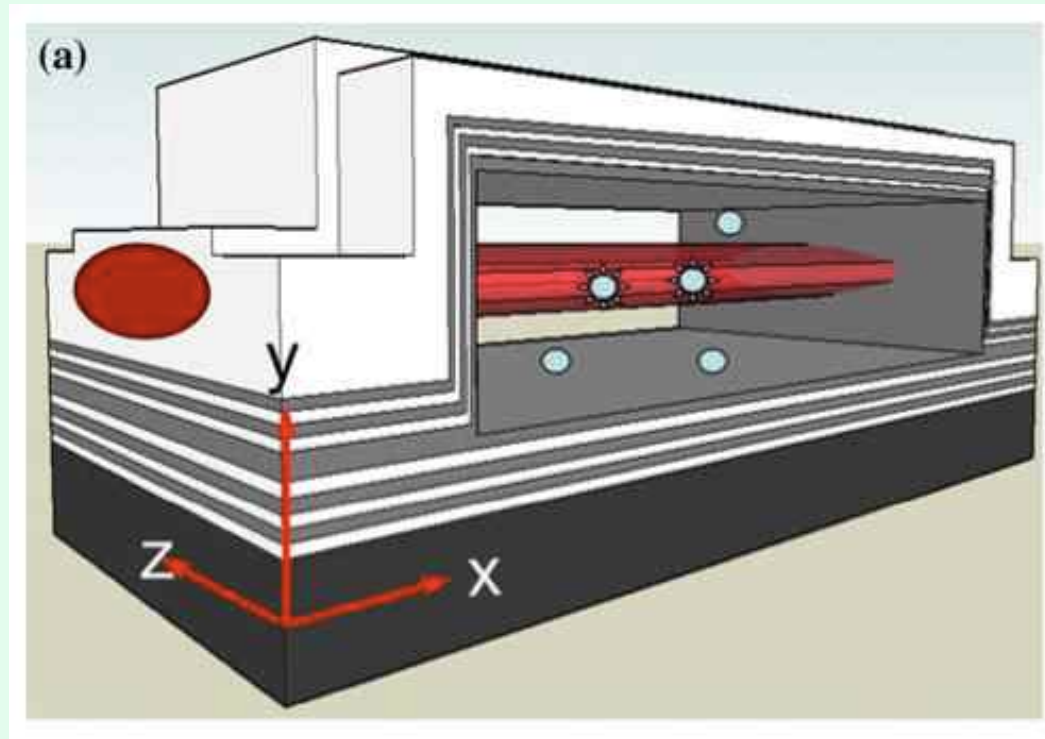


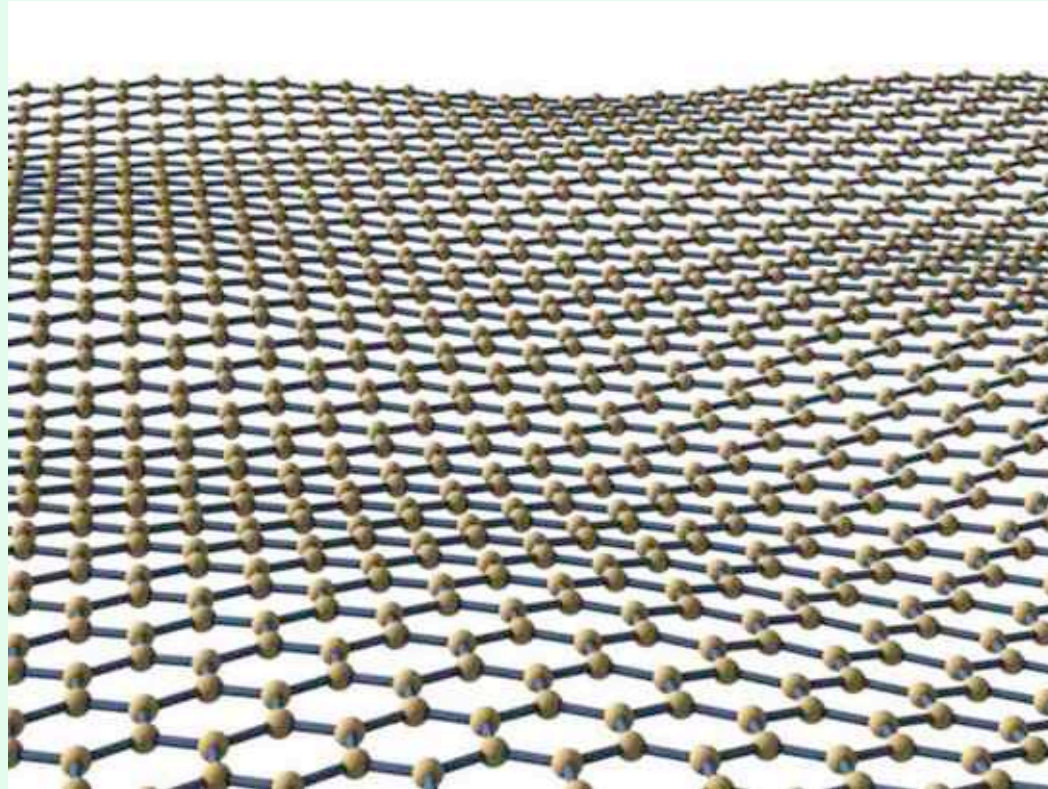






Fluorescence correlation spectroscopy (FCS), FRET, ...
Measure changes caused by molecular binding, not using the surface.



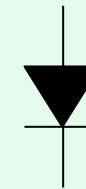
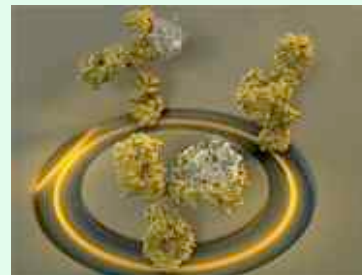


As it does not have volume, only surface, its entire structure is exposed to its environment and responds to any molecule that touches it. This makes it a good material for super-sensors capable of detecting single molecules of toxic gases.



Key issues Biology

1. Lab on a chip – chip on a lab: Integration.



2. Move away from surface affinity biosensor. Novel integrated sensor architectures.

